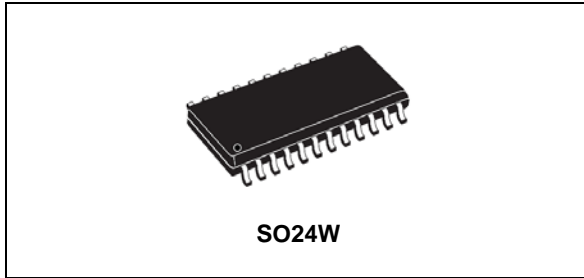


**Automotive galvanically isolated advanced single gate driver**

Datasheet - production data

**Features**

- Qualified for automotive applications according to AEC-Q100
- High voltage rail up to 1500 V
- Driver current capability: 5 A sink/source current at 25 °C
- dV/dt transient immunity  $\pm 50$  V/ns in full temperature range
- Overall input/output propagation delay: 100 ns
- Separate sink and source for easy gate driving configuration
- Negative gate drive ability
- Active Miller clamp
- Desaturation detection
- SENSE input
- $V_{CE}$  active clamping
- Output 2-level turn-off
- Diagnostic status output
- UVLO and OVLO functions
- Programmable input deglitch filter
- Asynchronous stop command
- Programmable deadtime, with violation error
- SPI interface for parameters programming
- Temperature warning and shutdown protection
- Self-diagnostic routines for protection features
- Full effective fault protection

**Applications**

- 600/1200 V inverters
- Inverters for EV/HEV
- EV charging stations
- Industrial drives
- UPS equipment
- DC/DC converters
- Solar inverters

**Description**

The STGAP1AS gapDRIVE™ is a galvanically isolated single gate driver for N-channel MOSFETs and IGBTs with advanced protection, configuration and diagnostic features. The architecture of the STGAP1AS isolates the channel from the control and the low voltage interface circuitry through true galvanic isolation. The gate driver is characterized by 5 A capability, making the device also suitable for high power inverter applications such as motor drivers in hybrid and electric vehicles and in industrial drives. The output driver section provides a rail-to-rail output with the possibility to use a negative gate driver supply. The input to output propagation delay results contained within 100 ns, providing high PWM control accuracy. Protection functions such as the Miller clamp, desaturation detection, dedicated sense pin for overcurrent detection, output 2-level turn-off, VCE overvoltage protection, UVLO and OVLO are included to easily design high reliability systems. Open drain diagnostic outputs are present and detailed device conditions can be monitored through the SPI. Each function's parameter can be programmed via the SPI, making the device very flexible and allowing it to fit in a wide range of applications. Separate sink and source outputs provide high flexibility and bill of material reduction for external components.

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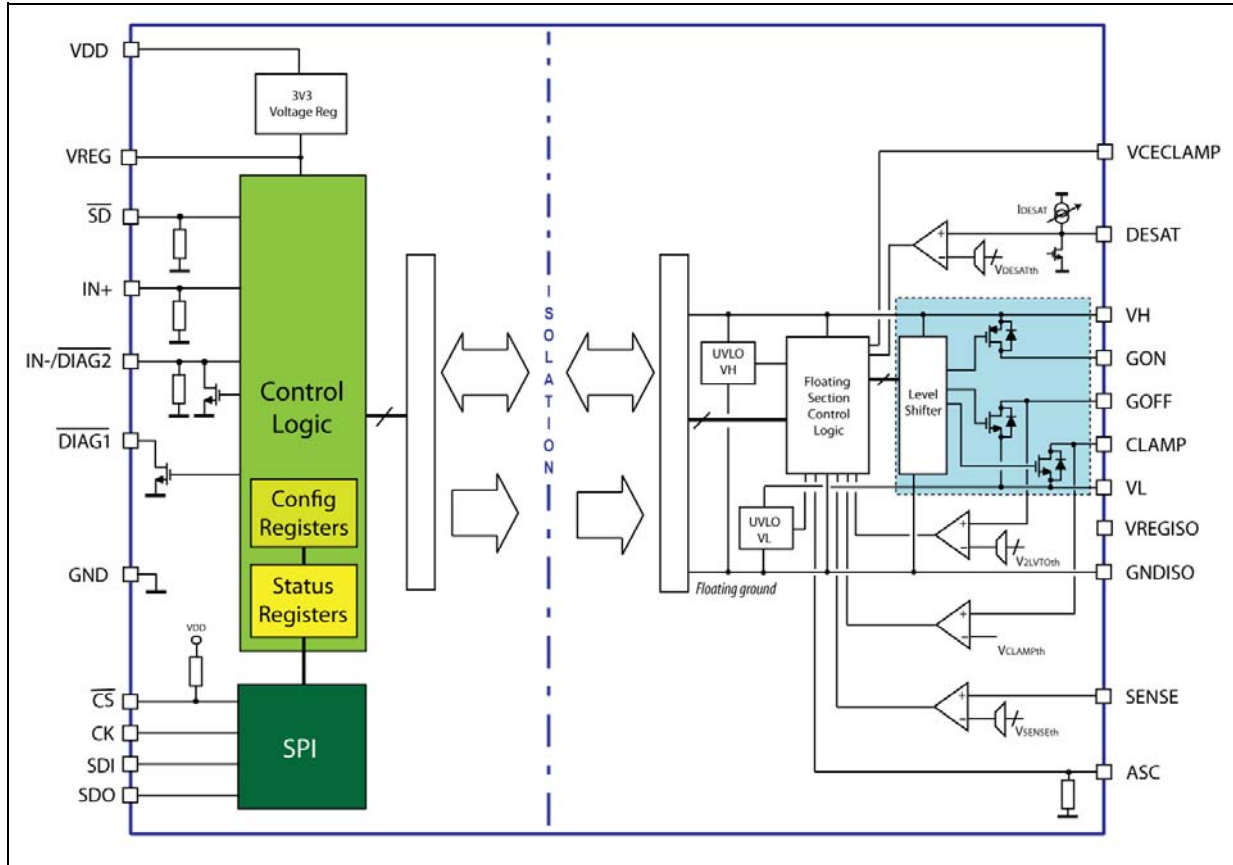
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# 1 Block diagram

Figure 1. Block diagram





## 2 Pin connection

Figure 2. Pin connection (top view)

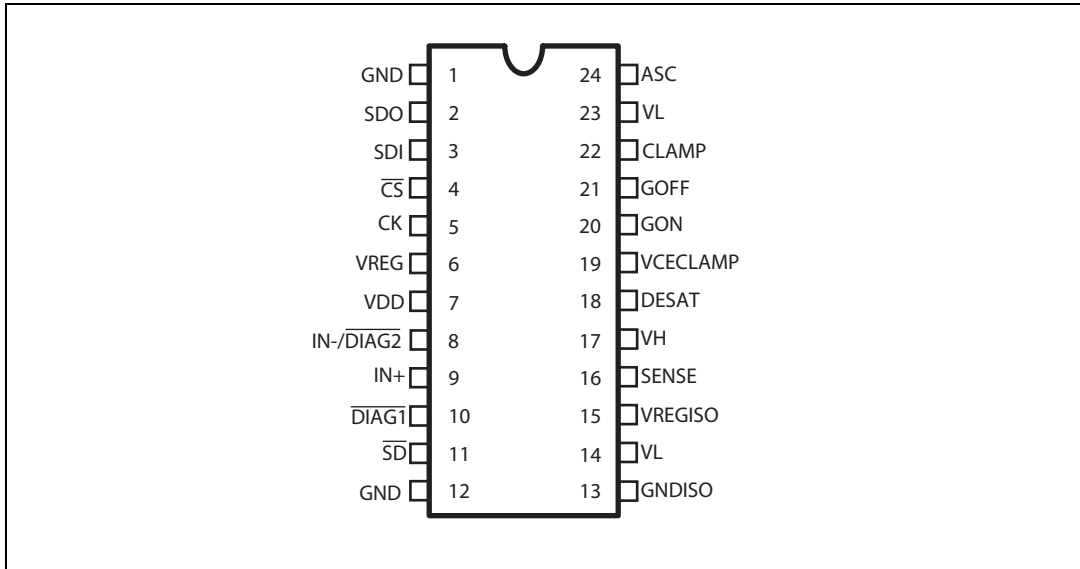


Table 1. Pin description

Pin no.	Pin name	Type	Function
7	VDD	Power supply	Power supply for low voltage section and internal 3.3 V regulator
6	VREG	Power supply	Internal 3.3 V regulator output and supply pin
11	$\overline{SD}$	Logic input	Shutdown input (active low)
9	IN+	Logic input	Gate command input
8	IN-/DIAG2	Logic input/open drain output	Gate command input /open drain diagnostic output
10	$\overline{DIAG1}$	Open drain output	Open drain diagnostic output
1, 12	GND	Ground	Low voltage section ground
4	$\overline{CS}$	Logic input	SPI chip select (active low)
5	CK	Logic input	SPI clock
3	SDI	Logic input	SPI serial data input
2	SDO	Logic output	SPI serial data output
19	VCECLAMP	Analog input	V <sub>CE</sub> active clamping protection
18	DESAT	Analog input/output	Desaturation protection
15	VREGISO	Power supply	Internal regulator output pin for decoupling
17	VH	Power supply	Positive power supply for high voltage section
20	GON	Analog output	Gate source output

Table 1. Pin description (continued)

Pin no.	Pin name	Type	Function
21	GOFF	Analog output	Gate sink output
22	CLAMP	Analog output	Miller clamp
14, 23	VL	Power supply	Negative power supply or ground for high voltage section
13	GNDISO	Ground	High voltage section (isolated) ground
16	SENSE	Analog input	Sense input for overcurrent protection
24	ASC	Analog input	Asynchronous stop command

### 3 Electrical data

#### 3.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Test condition	Min.	Max.	Unit
$dV_{ISO}/dt$	Common mode transient immunity	$V_{CM} = 1500\text{ V}$	-	50	V/ns
VDD	Low voltage section power supply voltage vs. GND	-	-0.30	6.50	V
VREG	Low voltage section internal regulator voltage vs. GND	-	-0.30	3.60	V
VREGISO	High voltage section internal regulator voltage vs. GNDISO	-	-0.30	3.60	V
$V_{LOGIC}$	Logic pins voltage vs. GND	-	-0.30	$VDD + 0.30$	V
VHL	Differential supply voltage (VH vs. VL)	-	-0.30	40	V
VH	Positive supply voltage (VH vs. GNDISO)	-	-0.30	40	V
VL	Negative supply voltage (VL vs. GNDISO)	-	-15	0.30	V
$V_{OUT}$	Voltage on gate driver outputs (GON, GOFF, CLAMP vs. VL)	-	$VL - 0.30$	$VH + 0.30$	V
$V_{DESAT}$	Voltage on DESAT pin vs. GNDISO	-	-0.30	$VH + 0.30$	V
$V_{SENSE}$	Voltage on SENSE pin vs. GNDISO	-	-2	$(VH + 0.30, 20)_{min}$	V
$V_{CECLAMP}$	Voltage on VCECLAMP pin vs. VL	-	$VL - 0.30$	$VH + 0.30$	V
$V_{ASC}$	Voltage on ASC pin vs. GNDISO	-	-0.30	$VH + 0.30$	V
$I_{DIAGx}$	Open drain DC output current	$V_{DIAGx} < 0.8\text{ V}$		20	mA
$V_{DIAGx}$	Open drain output voltage	-	-0.30	6.50	V
$T_J$	Junction temperature	-	-40	150	°C
$T_S$	Storage temperature	-	-50	150	°C
$T_A$	Ambient temperature	-	-40	125	°C
$P_{Din}$	Power dissipation input chip	-	-	65	mW
$P_{Dout}$	Power dissipation output chip	-	-	$(T_{J,max} - T_A)/R_{th(JA)} - P_{Din}$	W
$dH/dt$	Magnetic field immunity	-	-	100	A/(m·s)
ESD	Human body model	-		2	kV

### 3.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{th(JA)}$	Thermal resistance junction to ambient <sup>(1)</sup>	65	°C/W

1. The STGAP1AS mounted on the EVALSTGAP1AS rev 2.0 board (two-layer FR4 PCB).

### 3.3 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Pin	Parameter	Test condition	Min.	Max.	Unit
VH	17	Positive supply voltage (VH vs. GNDISO)	-	4.50 <sup>(1)</sup>	36	V
VL	14, 23	Negative supply voltage (VL vs. GNDISO)	-	GNDISO - 10	GNDISO <sup>(2)</sup>	V
VHL	-	Differential supply voltage (VH vs. VL)	-	-	36	V
VDD	7	Low voltage section power supply voltage vs. GND	-	4.50	5.50	V
VREG	6	Low voltage section internal regulator voltage vs. GND	(3)	3.3 ± 5%		V
V <sub>LOGIC</sub>	2, 3, 4, 5, 8, 9, 11	Logic pins voltage vs. GND	-	-	(VDD, 5) <sub>min</sub>	V
ASC	24	ASC pin voltage	-	GNDISO	(VH, 15) <sub>min</sub>	V
V <sub>DESATth</sub>	18	Desaturation protection threshold	DESAT enabled	-	VH - 1.50	V
f <sub>SW</sub>		Maximum switching frequency <sup>(4)</sup>	*	-	150	kHz

1. When UVLO is enabled this value is  $VH_{on,max}$ .
2. When UVLO is enabled this value is  $VL_{on,min}$ .
3. When VDD is connected to the VREG pin (refer to [Section 6 on page 22](#)).
4. Actual limit depends on power dissipation constraints.

## 4 Electrical characteristics

### 4.1 AC operation

**Table 5. AC operation electrical characteristics**  
( $T_j = -40$  to  $125$  °C,  $V_{DD} = 5$  V;  $V_H = 15$  V,  $V_L = GNDISO$ )

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
$t_{\text{deglitch}}$	8, 9, 11	Input deglitch time	INfilter = '11'	50	70	90	ns
			INfilter = '01'	100	160	220	ns
			INfilter = '10'	420	500	580	ns
$t_{\text{INmin}}$		Minimum propagated input pulse	INfilter = '00' and (2LTO_EN = '0' or 2LTOtime = 0x0)	-	-	20	ns
$t_{\text{Don}}$	8, 9, 11, 20	Input to output propagation delay ON	Deglitch filter and 2LTO disabled	90	100	130	ns
$t_{\text{Doff}}$	8, 9, 11, 21	Input to output propagation delay OFF	Deglitch filter and 2LTO disabled	90	100	130	ns
$t_r$	20	GON rise time	$V_L = 0$ V; $C_L = 2$ nF, 10% ÷ 90%	-	-	25	ns
$t_f$	21	GOFF rise time	$V_L = 0$ V $C_L = 2$ nF, 90% ÷ 10%	-	-	25	ns
PWD	8, 9, 11, 20, 21	Pulse width distortion $ t_{\text{Don}} - t_{\text{Doff}} $	$t_{\text{IN}} > 100$ ns Deglitch filter and 2LTO disabled	-	4	10	ns
DT	8, 9, 20, 21	Deadtime	DTset = '01'	205	250	295	ns
			DTset = '10'	650	800	945	
			DTset = '11'	985	1200	1415	
$t_{\text{release}}$	11	Minimum flag release time	$\overline{SD} = '0'$ , $SD\_FLAG = '1'$	-	-	105	$\mu\text{s}$

## 4.2 DC operation

**Table 6. DC operation electrical characteristics**  
( $T_j = -40$  to  $125$  °C,  $V_{DD} = 5$  V;  $V_H = 15$  V,  $V_L = GNDISO$ )

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
<b>Logic inputs/output</b>							
$V_{ol}$	2	SDO logic "0" output voltage	$I = 4$ mA	-	-	0.15	V
$V_{oh}$		SDO logic "1" output voltage	$I = 4$ mA	4.85	-	-	V
$I_{INh}$	8, 9	INx logic "1" input bias current	$V_{IN} = 5$ V (pin 8 used as IN-)	55	85	145	$\mu$ A
$I_{INl}$		INx logic "0" input bias current	$V_{IN} = 0$ V (pin 8 used as IN-)	-	-	0.10	$\mu$ A
$I_{SDh}$	11	$\overline{SD}$ logic "1" input bias current	$V_{SD} = 5$ V	55	85	145	$\mu$ A
$I_{SDl}$		$\overline{SD}$ logic "0" input bias current	$V_{SD} = 0$ V	-	-	0.10	$\mu$ A
$R_{in\_pd}$	8, 9, 11	Input pull-down resistors	$V_{IN} = 5$ V (pin 8 used as IN-)	35	60	85	k $\Omega$
$R_{in\_pu}$	4	$\overline{CS}$ input pull-up resistor	$\overline{CS} = GND$	35	55	80	k $\Omega$
$V_{il}$	3, 4, 5,	Low logic level voltage	-	$0.29 \cdot V_{DD}$	$0.33 \cdot V_{DD}$	$0.37 \cdot V_{DD}$	V
$V_{ih}$	8, 9, 11	High logic level voltage	-	$0.62 \cdot V_{DD}$	$0.66 \cdot V_{DD}$	$0.79 \cdot V_{DD}$	V
<b>Driver buffer section</b>							
$I_{GON}$	20	Source short-circuit current	$V_{IN} < V_{ih}$ , $T_{pulse} < 5$ $\mu$ s, DC = 1% $T_j = 25$ °C $T_j = -40 \div +125$ °C	2.50	5	7	A
$I_{GOFF}$	21	Sink short-circuit current	$V_{IN} < V_{ih}$ , $T_{pulse} < 5$ $\mu$ s, DC = 1% $T_j = 25$ °C $T_j = -40 \div +125$ °C	2.50	5	6	A
$V_{GOFFL}$	21	GOFF output low level voltage	$I_{GOFF} = 0.1$ A $I_{GOFF} = 1$ A	$V_L + 0.03$ $V_L + 0.50$	$V_L + 0.09$ $V_L + 1$	$V_L + 0.15$ $V_L + 1.80$	V
$V_{GONH}$	20	GON output high level voltage	$I_{GON} = 0.1$ A $I_{GON} = 1$ A	$V_H - 0.18$ $V_H - 2.10$	$V_H - 0.10$ $V_H - 1.30$	$V_H - 0.05$ $V_H - 0.50$	V
SafeClp	20, 21, 22	GOFF active clamp	$I_{GOFF} = 0.2$ A; VH floating; GON = GOFF = CLAMP	-	-	3	V

**Table 6. DC operation electrical characteristics**  
 (T<sub>j</sub> = -40 to 125 °C, VDD = 5 V; VH = 15 V, VL = GNDISO) (continued)

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
<b>Supply voltage</b>							
I <sub>REG</sub>	6	VREG short-circuit current (see <a href="#">Section 7.3 on page 29</a> )	0.1 V < VREG < 3.0 V	-	60	120	mA
			VREG < 0.1 V	-	15	35	
VDD <sub>on</sub>	7	VDD UVLO turn-on threshold	-	3.95	4.10	4.30	V
VDD <sub>off</sub>		VDD UVLO turn-off threshold	-	3.65	3.80	4	V
VDD <sub>hys</sub>		VDD UVLO hysteresis	-	0.15	-	-	V
OVVDD <sub>on</sub>		VDD OVLO turn-on threshold	-	5.30	5.50	5.90	V
OVVDD <sub>off</sub>		VDD OVLO turn-off threshold	-	5.40	5.70	6.10	V
OVVDD <sub>hys</sub>		VDD OVLO hysteresis	-	100	200	300	mV
I <sub>QDD</sub>	7	VDD quiescent supply current	VDD = 5 V; SD = 5 V; INx = GND; f = 0 Hz	5.20	6.50	7.50	mA
			VDD = 5 V; SD = 5 V; f <sub>SW</sub> = f <sub>SW,max</sub>	6.00	8.50	9.50	mA
VH <sub>on</sub>	17	VH UVLO turn-on threshold	VHONth = '01'	9.40	10	10.50	V
			VHONth = '10'	11.30	12	12.60	
			VHONth = '11'	13.15	14	14.70	
VH <sub>off</sub>		VH UVLO turn-off threshold	VHONth = '01'	8.45	9	9.45	V
			VHONth = '10'	10.35	11	11.55	
			VHONth = '11'	12.25	13	13.65	
VH <sub>hyst</sub>	VH UVLO hysteresis	-	0.70	1	1.30	V	
VL <sub>on</sub>	14, 23	VL UVLO turn-on threshold	VLONth = '01'	-3.15	-3	-2.80	V
			VLONth = '10'	-5.25	-5	-4.70	
			VLONth = '11'	-7.35	-7	-6.55	
VL <sub>off</sub>		VL UVLO turn-off threshold	VLONth = '01'	-2.15	-2	-1.90	V
			VLONth = '10'	-4.25	-4	-3.80	
			VLONth = '11'	-6.35	-6	-5.70	
VL <sub>hys</sub>	VL UVLO hysteresis	-	0.70	1	1.20	V	

**Table 6. DC operation electrical characteristics**  
 (T<sub>j</sub> = -40 to 125 °C, VDD = 5 V; VH = 15 V, VL = GNDISO) (continued)

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
OV <sub>VHoff</sub>	17	VH OVLO turn-off threshold	OVLO_EN = '1'	17.80	19	20	V
OV <sub>VHon</sub>		VH OVLO turn-on threshold	OVLO_EN = '1'	16.90	18	18.90	V
OV <sub>VHhys</sub>		VH OVLO hysteresis	OVLO_EN = '1'	0.60	1	1.30	V
OV <sub>VLoff</sub>	14, 23	VL OVLO turn-off threshold	OVLO_EN = '1'	-10.50	-10	-9.40	V
OV <sub>VLon</sub>		VL OVLO turn-on threshold	OVLO_EN = '1'	-9.45	-9	-8.55	V
OV <sub>VLhyst</sub>		VL OVLO hysteresis	OVLO_EN = '1'	0.70	1	1.30	V
I <sub>QH</sub>	17	VH quiescent supply current	$\overline{SD} = 5\text{ V};$ IN+ = 5 V; IN- = GND	5	6.70	7.50	mA
I <sub>QL</sub>	14, 23	VL quiescent supply current	$\underline{VL} = -5\text{ V};$ SD = 5 V; IN+ = IN- = GND	300	420	550	μA
<b>Desaturation protection</b>							
V <sub>DESATth</sub>	18	Desaturation threshold	DESATth = '000';	2.60	3	3.10	V
			DESATth = '001'	3.60	4	4.20	
			DESATth = '010'	4.60	5	5.30	
			DESATth = '011'	5.50	6	6.30	
			DESATth = '100'	6.50	7	7.40	
			DESATth = '101'	7.40	8	8.40	
			DESATth = '110'	8.30	9	9.40	
t <sub>DESfilter</sub>	18	DESAT pin deglitch filter	DESATth = '100' <sup>(1)</sup>	10	20	30	ns
I <sub>DESAT</sub>	18	DESAT blanking charge current	DESATcur = '00'; V <sub>DESAT</sub> = 0 V	220	250	265	μA
			DESATcur = '01'; V <sub>DESAT</sub> = 0 V	440	500	525	
			DESATcur = '10'; V <sub>DESAT</sub> = 0 V	660	750	800	
			DESATcur = '11'; V <sub>DESAT</sub> = 0 V	885	1000	1050	
I <sub>DESoff</sub>	18	DESAT blanking discharge current	V <sub>DESAT</sub> = 8 V	50	70	90	mA



**Table 6. DC operation electrical characteristics**  
 (T<sub>j</sub> = -40 to 125 °C, VDD = 5 V; VH = 15 V, VL = GNDISO) (continued)

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
t <sub>BLK</sub>	18	DESAT protection fixed blanking time		160	250	340	ns
t <sub>DESAT</sub>		DESAT protection intervention time	V <sub>DESAT</sub> = V <sub>DESATh</sub> to GOFF 90% C <sub>LOAD</sub> = 10 nF 2LTO disabled	80	150	220	ns
<b>SENSE overcurrent function</b>							
V <sub>SENSEth</sub>	16	SENSE protection threshold	SENSEth = '000'	88	100	112	mV
			SENSEth = '001'	110	125	140	
			SENSEth = '010'	135	150	165	
			SENSEth = '011'	158	175	192	
			SENSEth = '100'	185	200	215	
			SENSEth = '101'	235	250	268	
			SENSEth = '110'	285	300	315	
			SENSEth = '111'	380	400	420	
t <sub>SENSE</sub>		SENSE protection intervention time	SENSEth = '111' 0 → 1 V step on V <sub>SENSE</sub> to GOFF 90%; C <sub>LOAD</sub> = 10 nF 2LTO disabled	-	95	120	ns
<b>2-level turn-off function</b>							
V <sub>2LTOth</sub>	21	2LTO threshold	2LTOth = '0000'	6.65	7.00	7.35	V
			2LTOth = '0001'	7.12	7.50	7.88	
			2LTOth = '0010'	7.60	8.00	8.40	
			2LTOth = '0011'	8.07	8.50	8.93	
			2LTOth = '0100'	8.55	9.00	9.45	
			2LTOth = '0101'	9.02	9.50	9.98	
			2LTOth = '0110'	9.50	10.00	10.50	
			2LTOth = '0111'	9.97	10.50	11.03	
			2LTOth = '1000'	10.45	11.00	11.55	
			2LTOth = '1001'	10.92	11.50	12.08	
			2LTOth = '1010'	11.40	12.00	12.60	
			2LTOth = '1011'	11.87	12.50	13.13	
			2LTOth = '1100'	12.35	13.00	13.65	
			2LTOth = '1101'	12.82	13.50	14.18	
			2LTOth = '1110'	13.30	14.00	14.70	
2LTOth = '1111'	13.77	14.50	15.23				

**Table 6. DC operation electrical characteristics**  
 (T<sub>j</sub> = -40 to 125 °C, VDD = 5 V; VH = 15 V, VL = GNDISO) (continued)

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
t <sub>2LTOtime</sub>	21	2LTO time	2LTOtime = '0001'	0.64	0.75	0.89	μs
			2LTOtime = '0010'	0.89	1.00	1.15	
			2LTOtime = '0011'	1.36	1.50	1.65	
			2LTOtime = '0100'	1.83	2.00	2.18	
			2LTOtime = '0101'	2.30	2.50	2.70	
			2LTOtime = '0110'	2.77	3.00	3.23	
			2LTOtime = '0111'	3.25	3.50	3.75	
			2LTOtime = '1000'	3.47	3.75	4.03	
			2LTOtime = '1001'	3.71	4.00	4.29	
			2LTOtime = '1010'	3.94	4.25	4.56	
			2LTOtime = '1011'	4.18	4.50	4.82	
			2LTOtime = '1100'	4.42	4.75	5.08	
			2LTOtime = '1101'	4.66	5.00	5.34	
			2LTOtime = '1110'	4.90	5.25	5.63	
2LTOtime = '1111'	5.12	5.50	5.95				
<b>Diagnostic outputs</b>							
t <sub>DIAG1,2</sub>	8, 10	Fault event to $\overline{\text{DIAGx}}$ Low delay	Fault event to $\overline{\text{DIAGx}}$ 90%	-	5	-	μs
I <sub>DIAG1</sub>		$\overline{\text{DIAG1}}$ low level sink current	V <sub>DIAG1</sub> = 0.4 V	10	18	30	mA
I <sub>DIAG2</sub>		$\overline{\text{DIAG2}}$ low level sink current	V <sub>DIAG2</sub> = 0.4 V	10	18	30	mA
R <sub>DIAG1,2</sub>		$\overline{\text{DIAGx}}$ pull-down resistor	-	300	550	800	kΩ
<b>Clamp Miller function</b>							
V <sub>CLAMPth</sub>	22	CLAMP voltage threshold	CLAMP vs. GNDISO	1.70	2	2.30	V
I <sub>CLAMP</sub>		Clamp short-circuit current	V <sub>IN</sub> < V <sub>ih</sub> , T <sub>pulse</sub> < 5 μs, DC = 1% T <sub>j</sub> = 25 °C T <sub>j</sub> = -40 ÷ +125 °C	2.50	5	6	A
V <sub>CLAMP_L</sub>		Clamp low level output voltage	I <sub>CLAMP</sub> = 1 A	VL + 0.50	VL + 1	VL + 1.80	V
<b>V<sub>CE</sub> active clamping protection</b>							
V <sub>VCECLth</sub>	19	V <sub>CE</sub> clamping threshold	-	VL + 1.20	VL + 1.60	VL + 2	V
V <sub>VCECLhyst</sub>		V <sub>CE</sub> clamping threshold hysteresis	-	0.30	0.50	0.60	V

**Table 6. DC operation electrical characteristics**  
**( $T_j = -40$  to  $125$  °C,  $V_{DD} = 5$  V;  $V_H = 15$  V,  $V_L = GNDISO$ ) (continued)**

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit	
$t_{VCECLOff}$	19	$V_{CE}$ clamping time-out	-	2	2.30	2.60	$\mu s$	
$t_{VCECL}$		$V_{CE}$ clamping intervention time <sup>(1)</sup>	-	-	20	-	ns	
<b>ASC function</b>								
$V_{ASCI}$	24	Low logic level voltage	-	0.80	1.10	1.40	V	
$V_{ASCh}$		High logic level voltage	-	1.80	2.20	2.40	V	
$I_{ASCh}$		ASC logic "1" input bias current	$V_{ASC} = 5$ V	-	55	100	145	$\mu A$
$I_{ASCI}$		ASC logic "0" input bias current	$V_{ASC} = 0$ V	-	-	-	0.10	$\mu A$
$R_{ASC}$		ASC pull-down resistors	$V_{ASC} = 5$ V	-	35	50	70	$k\Omega$
$t_{ASC}$		ASC intervention time	$V_{ASC} = 5$ V	-	100	-	250	ns
<b>Functionality checks</b>								
$t_{Gchk}$	20, 21	Gate path check time (GON/GOFF) <sup>(2)</sup>	-	-	-	30	$\mu s$	
$V_{Gchk}$	20	Gate path check voltage (GON)	-	$0.7 \times V_H$	$0.76 \times V_H$	$0.84 \times V_H$	V	
$t_{Rchk}$	16	SENSE resistor check time	-	-	-	15	$\mu s$	
$I_{GOFFchk}$	21	GOFF path check current	-	-420	-350	-280	$\mu A$	
$I_{SENSERchk}$	16	SENSE resistor check current	$V_{SENSE} < 1$ V	8	10	12	$\mu A$	
$t_{SENSEchk}$		SENSE comparator check time	-	-	-	15	$\mu s$	
$t_{DESATchk}$	18	DESAT comparator check time	-	-	-	15	$\mu s$	
<b>Overtemperature protection</b>								
$T_{WN}$	-	Warning temperature <sup>(1)</sup>	-	125	-	-	°C	
$T_{SD}$	-	Shutdown temperature <sup>(1)</sup>	-	155	-	-	°C	
$T_{hys}$	-	Temperature hysteresis <sup>(1)</sup>	-	-	20	-	°C	
<b>Standby</b>								
$I_{STBY\_VDD}$	7	VDD standby current	$V_{DD} = 5$ V	0.40	0.80	1	mA	
$t_{sleep}$	-	Standby time	$\overline{SD} = '0'$ , measured from $\overline{CS}$ rise	500	700	900	ns	
$t_{awake}$	-	Logic wake-up time <sup>(1)</sup>	$\overline{SD} = '1'$	5	-	-	$\mu s$	

**Table 6. DC operation electrical characteristics**  
 (T<sub>j</sub> = -40 to 125 °C, VDD = 5 V; VH = 15 V, VL = GNDISO) (continued)

Symbol	Pin	Parameter	Test condition	Min.	Typ.	Max.	Unit
<b>SPI<sup>(1)</sup></b>							
t <sub>CKmax</sub>	5	Maximum SPI clock frequency	-	5	-	-	MHz
t <sub>rCK</sub> t <sub>fCK</sub>		SPI clock rise and fall time	CL = 30 pF	-	-	25	ns
t <sub>hCK</sub> t <sub>iCK</sub>		SPI clock high and low time	-	75	-	-	ns
t <sub>setCS</sub>	4	$\overline{\text{CS}}$ setup time	-	350	-	-	ns
t <sub>holCS</sub>		$\overline{\text{CS}}$ hold time	-	10	-	-	ns
t <sub>desCS</sub>	4	$\overline{\text{CS}}$ deselect time <sup>(3)</sup>	Local register read	800	-	-	μs
			Remote register read	30	-	-	
			Start configuration	22	-	-	
			Stop configuration	5	-	-	
			Reset status register	50	-	-	
			Any other command	700	-	-	ns
t <sub>setSDI</sub>	3	SDI setup time	-	25	-	-	ns
t <sub>holSDI</sub>		SDI hold time	-	20	-	-	ns
t <sub>enSDO</sub>	2	SDO enable time	-	-	-	38	ns
t <sub>disSDO</sub>		SDO disable time	-	-	-	47	ns
t <sub>vSDO</sub>		SDO valid time	-	-	-	57	ns
t <sub>holSDO</sub>		SDO hold time	-	37	-	-	ns
t <sub>SDLCSL</sub>	4,11	$\overline{\text{SD}}$ falling to $\overline{\text{CS}}$ falling	-	350	-	-	ns
t <sub>CSHSDH</sub>	4,11	$\overline{\text{CS}}$ rising to $\overline{\text{SD}}$ rising	-	350	-	-	ns

1. Characterization data, not tested in production.
2. The actual waiting time depends on the gate charge size.
3. See [Table 22 on page 52](#) and [Section 9.1.3 on page 50](#).

## 5 Isolation

**Table 7. Isolation and safety-related specifications**

Parameter	Symbol	Value	Unit	Conditions
Clearance (minimum external air gap)	CLR	8	mm	Measured from input terminals to output terminals, shortest distance through air
Creepage (minimum external tracking)	CPG	8	mm	Measured from input terminals to output terminals, shortest distance path along body
Comparative tracking index (tracking resistance)	CTI	≥ 400	-	DIN IEC 112/VDE 0303 Part 1
Isolation group	-	II	-	Material group (DIN VDE 0110, 1/89, Table 1)

**Table 8. IEC 60747-5-2 isolation characteristics**

Parameter	Symbol	Test conditions	Characteristic	Unit
Installation classification (EN 60664-1, Table 1 - see <sup>(1)</sup> ) For rated mains voltage ≤ 150 V <sub>rms</sub> For rated mains voltage ≤ 300 V <sub>rms</sub> For rated mains voltage ≤ 600 V <sub>rms</sub>	-	-	I - IV I - III I - II	-
Pollution degree (EN 60664-1)	-	-	2	-
Maximum working isolation voltage	V <sub>IORM</sub>	-	1500	V <sub>PEAK</sub>
Input to output test voltage as per IEC 60747-5-2	V <sub>PR</sub>	Method a, type test V <sub>PR</sub> = V <sub>IORM</sub> × 1.6, t <sub>m</sub> = 10 s Partial discharge < 5 pC	2400	V <sub>PEAK</sub>
		Method b, 100 % production test V <sub>PR</sub> = V <sub>IORM</sub> × 1.875, t <sub>m</sub> = 1 s Partial discharge < 5 pC	2815	V <sub>PEAK</sub>
Transient overvoltage as per IEC 60747-5-2 (highest allowable overvoltage)	V <sub>IOTM</sub>	t <sub>ini</sub> = 60 s type test	4000	V <sub>PEAK</sub>
Maximum surge isolation voltage	V <sub>IOSM</sub>	Type test	4000	V <sub>PEAK</sub>
Isolation resistance	R <sub>IO</sub>	V <sub>IO</sub> = 500 V at T <sub>S</sub>	>10 <sup>9</sup>	Ω

1. For three-phase systems the values in the table refer to the line-to-neutral voltage.

**Table 9. Isolation voltage as per UL 1577**

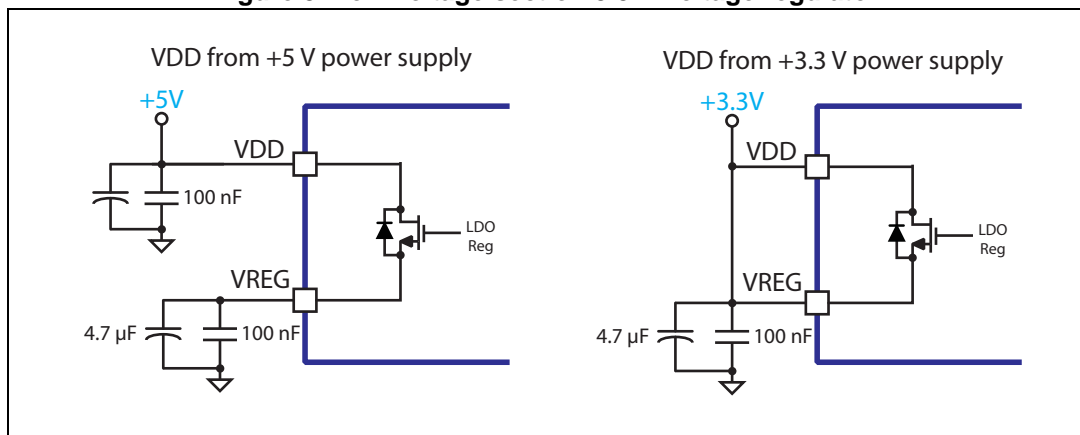
Description	Symbol	Characteristic	Unit
Isolation withstand voltage, 1 min. (type test)	V <sub>ISO</sub>	2500\3536	V <sub>rms</sub> \V <sub>PEAK</sub>
Isolation withstand test, 1 sec. (100% production)	V <sub>ISOtest</sub>	3000\4245	V <sub>rms</sub> \V <sub>PEAK</sub>

## 6 Logic supply management

### 6.1 Low voltage section voltage regulator

The device integrates in the low voltage section a linear voltage regulator that can be used to obtain the 3.3 V logic core supply voltage from an external 5 V supply voltage. If an external 3.3 V supply voltage is available the VDD and VREG have to be shorted as shown in [Figure 3](#). The logic IOs are referred to the VDD voltage (see [Table 6 on page 14](#) for details).

**Figure 3. Low voltage section 3.3 V voltage regulator**



Undervoltage protection is available on the VDD supply pin (disabled by default).

When the VDD voltage goes below the  $V_{DDoff}$  threshold the device and its outputs goes in “safe state” (see [Section 6.3](#)) and the UVLOD status flag is forced low. Once the protection is triggered, the UVLOD flag is latched and the device remains in “safe state” until the UVLOD flag is not released. See [Section 7.11 on page 35](#) for indication on how the failure flags can be released.

This protection can be enabled writing the UVLOD\_EN bit of the CFG1 register (disabled by default).

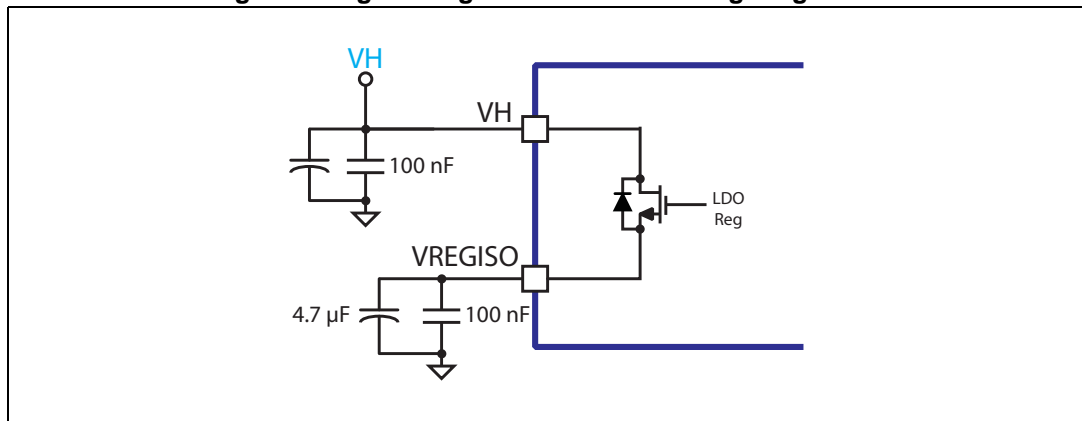
Oversvoltage protection is available on the VDD supply pin.

When the VDD voltage goes over the  $OV_{VDDoff}$  threshold the device and its outputs goes in “safe state” and the OVLOD status flag is set. The device remains in “safe state” and the OVLOD flag is latched, see [Section 7.11](#) for indication on how the failure flags can be released.

## 6.2 High voltage section voltage regulator

The device integrates in the high voltage section a linear voltage regulator that generates the 3.3 V logic core supply voltage from an external supply voltage connected to the VH pin.

Figure 4. High voltage section 3.3 V voltage regulator



If the voltage at the VREGISO pin goes below the minimum operating threshold which causes the logic reset, the REGERRR bit in the STATUS2 register is set high.

## 6.3 Power-up, power-down and “safe state”

The following conditions define the device's “safe state”:

- GOFF = ON state
- GON = high impedance
- CLAMP = ON state (if  $CLAMP < GNDISO + V_{CLAMPth}$ )
- DESAT = GNDISO (internal switch on and current generator off)

Such conditions are guaranteed at power-up of the isolated side (also for  $VH < VH_{on}$  and  $VL > VL_{on}$ ) and during the whole device power-down phase (also for  $VH < VH_{off}$  and  $VL > VL_{off}$ ), whatever the value of the input pins.

The device integrates a structure which clamps the driver output to a voltage smaller than SafeClp when the VH voltage is not high enough to actively turn the Goff N-channel MOSFET on.

If the VH positive supply pin is floating the GOFF pin is clamped to a voltage smaller than SafeClp.

After power-up of the isolated side the REGERRR status flag is latched and the device is forced in “safe state”. See [Section 7.11 on page 35](#) for indication on how the failure flags can be released.

After power-up of the low voltage side the REGERRL and UVLOD status flags are latched and the device is forced in “safe state”. See [Section 7.11](#) for indication on how the failure flags can be released.

The UVLOH flag is also forced high at the power-up of the low voltage side, but its value is set to zero as soon as the isolated side power-up is completed.

## 6.4 Standby function

The device can be put in standby mode to reduce the power consumption on VDD via the SPI command "Sleep" (refer to [Section 9.1.5 on page 51](#)).

The proper sequence is:

1. Pull-down the  $\overline{SD}$  pin: the driver section will be put in "safe state"
2. Send a Sleep command
3. After a  $t_{\text{sleep}}$  time the device can be considered actually in the sleep mode.

To exit from the sleep mode it is necessary to set the  $\overline{SD}$  high for at least  $t_{\text{awake}}$  while keeping IN+ low.

After a  $t_{\text{awake}}$  time the device can accept new commands and the REGERRR bit is set to indicate that the device needs to be reprogrammed.

If the  $\overline{SD}$  pin is raised while  $t_{\text{sleep}}$  is still not expired, the device returns to the operation mode within a  $t_{\text{awake}}$  time.



## 7 Functional description

### 7.1 Inputs and outputs

The device is controlled through following logic inputs:

- $\overline{SD}$ : active low shutdown input
- $IN+$ : driver input
- $\overline{CS}$ : active low chip select (SPI)
- $SDI$ : serial data input (SPI)
- $CK$ : serial clock (SPI)

And following logic outputs:

- $SDO$ : serial logic output (SPI)
- $DIAG1$ : diagnostic signal (open drain)

And following IO pin:

- $IN/\overline{DIAG2}$ : driver input or diagnostic open drain output.

Logic input thresholds and output ranges vary according to VDD voltage. In particular, the device is designed to work with VDD supply voltages of 5 V or 3.3 V.

The operation of the driver IOs can be programmed through  $DIAG\_EN$  bits as described in [Table 10](#).

**Table 10. Inputs true table (device NOT in “safe state”)**

Bit in CFG1 register	Input pins			Output pins	
	$\overline{SD}$	$IN+$	$IN-$	GON	GOFF
X	0	X	X	OFF	ON
0	1	0	0	OFF	ON
0	1	0	1	OFF	ON
0	1	1	0	ON	OFF
0	1	1	1	OFF	ON
1	1	0	X <sup>(1)</sup>	OFF	ON
1	1	1	X <sup>(1)</sup>	ON	OFF

1. The  $IN/\overline{DIAG2}$  pin is used as the open drain output for diagnostic signaling (refer to [Section 7.11 on page 35](#)).

A deglitch filter is applied to device inputs ( $\overline{SD}$ ,  $IN+$ ,  $IN-$ ). Each input pulse, positive and negative, shorter than the programmed  $t_{deglitch}$  value is neglected by internal logic.

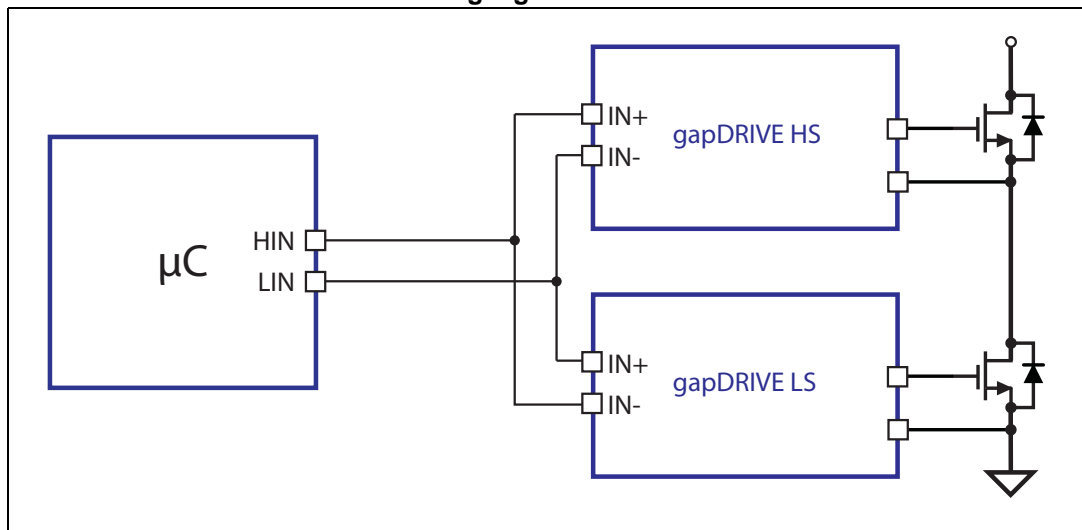
De-glitch time can be programmed as listed in [Table 30 on page 54](#).

When the deglitch filter is disabled ( $INfilter = '00'$ ) and the 2-level turn-off function is disabled ( $2LTOtime = 0x0$ ) or enabled only after a fault event ( $2LTO\_EN = '0'$ ), a minimum input pulse  $t_{INmin}$  is required to change the device output status. The minimum input pulse timing filters out both positive and negative pulses at the  $IN+$ ,  $IN-$  and  $\overline{SD}$  pins.

## 7.2 Deadtime and interlocking

When single gate drivers are used in half-bridge configuration, they usually do not allow preventing cross conduction in case of wrong input signals coming from the controller device. This limitation is due to the fact that each driver does not have the possibility to know the status of the input signal of the other companion driver in the same leg. Thanks to the availability of two input pins with opposite polarity the STGAP1AS allows implementing an hardware interlocking that prevents cross conduction even in case of wrong input signals generated by the control unit. This functionality can be achieved by implementing the connection shown in [Figure 5](#) and by configuring the IN-/DIAG2 pin as input (which is its default configuration).

**Figure 5. HW cross conduction prevention in half-bridge configuration with two single gate drivers**



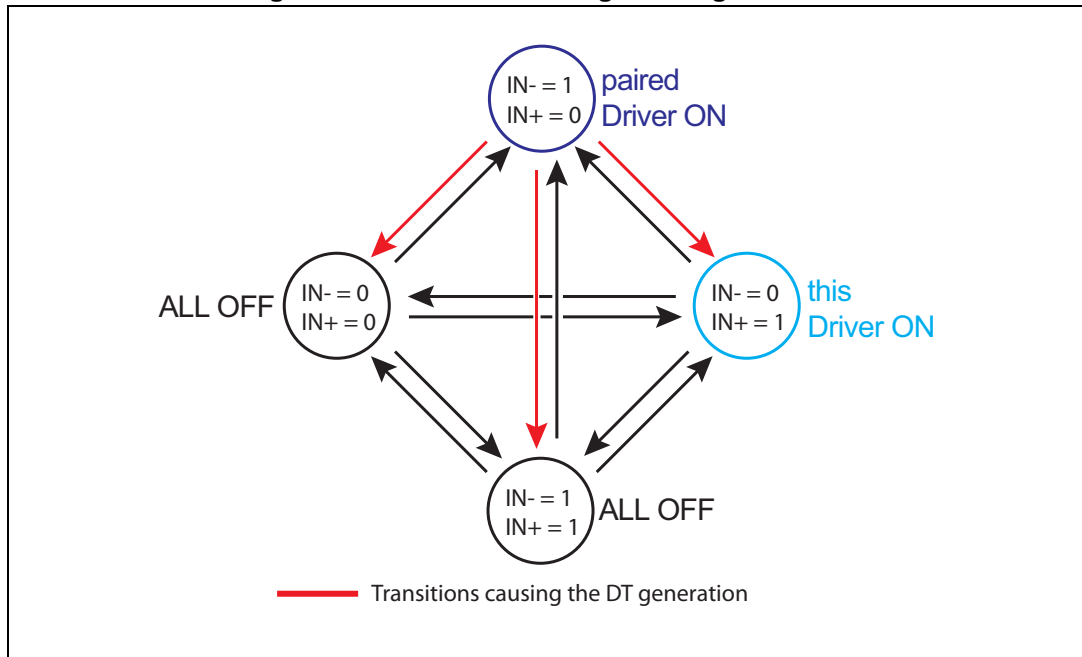
When such configuration is used, it is also possible to enable the STGAP1AS programmable deadtime feature, which guarantees that at least a DT time passes between the turn-off of one driver's output and the turn-on of the other driver. The deadtime value DT can be programmed through the SPI interface as shown in [Table 29 on page 54](#).

If the deadtime feature is enabled, a counter is started when the input status changes from  $\langle \text{IN-} = '1' \text{ and } \text{IN+} = '0' \rangle$  to a different combination, which means that the other driver in the same leg is at the beginning of a turn-off (refer to [Figure 6](#)).

Once the counter is started it keeps counting regardless of any input variation until a DT time has passed, and during this time the driver prevents the turn-on of its output even if the controller tries to force the turn-on (inputs set to  $\langle \text{IN-} = '0' \text{ and } \text{IN+} = '1' \rangle$ ).

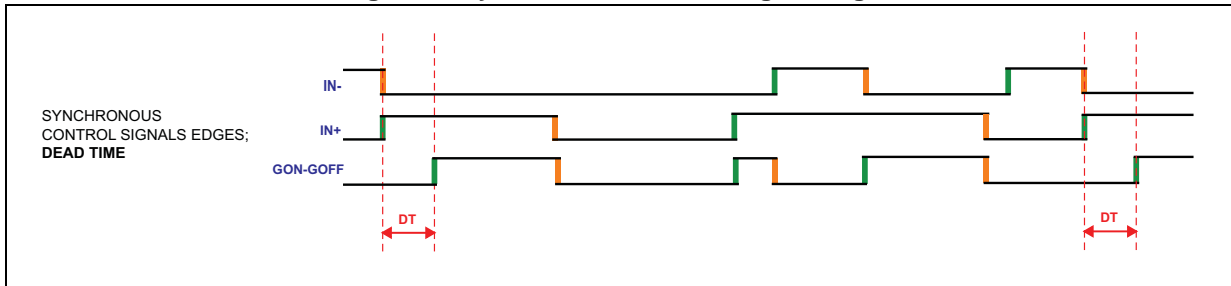
Once the programmed DT counter is expired, the driver immediately turns the output on as soon as a turn-on command is present at the input pins, and no extra delay is added.

Figure 6. Transitions causing the DT generation

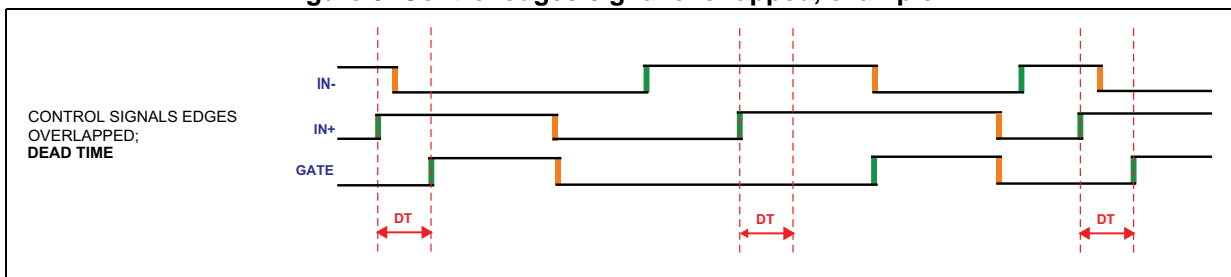


Some examples of the device behavior when the deadtime feature is enabled are shown from [Figure 7](#) to [Figure 10](#).

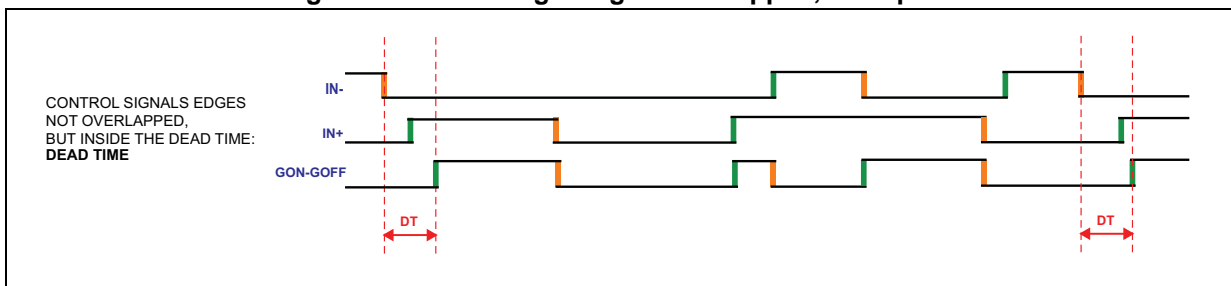
**Figure 7. Synchronous control signal edges**



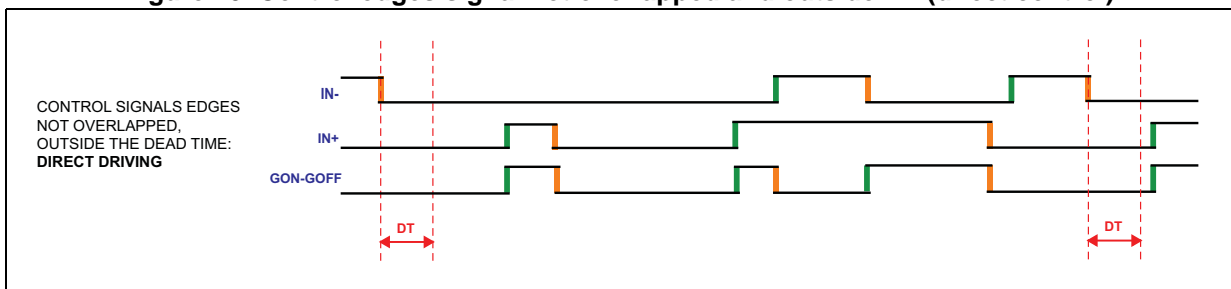
**Figure 8. Control edges signal overlapped, example 1**



**Figure 9. Control edges signal overlapped, example 2**



**Figure 10. Control edges signal not overlapped and outside DT (direct control)**



When the deadtime function is enabled the STGAP1AS reports a “deadtime violation” fault in case the control unit tries to turn on any of the drivers in one leg during the counting of the programmed DT time. If such event occurs the DT\_ERR flag is set high and latched.

## 7.3 Hardware RESET

The device can be reset by forcing the VREG pin to ground through an external switch.

The internal regulator is designed to stand this condition.

The maximum current required to force the VREG pin to ground is indicated by the parameter  $I_{REG}$ .

## 7.4 Power supply UVLO and OVLO

Undervoltage protection is available on both VH and VL supply pins.

The turn-on threshold can be programmed through the SPI writing the CFG4 register. A fixed 1 V hysteresis will set the respective turn-off threshold.

Both UVLO protections can be independently disabled by setting the proper value in the CFG4 register.

When VH voltage goes below the  $VH_{off}$  threshold the output buffer goes in “safe state” and the UVLOH status flag is forced high. If the UVLOlatch bit in the CFG4 register is set low (default), the UVLOH status flag is released when VH voltage reaches the  $VH_{on}$  threshold and the device returns to normal operation.

Otherwise the UVLOH flag is latched and the device remains in “safe state” until the VH voltage reaches the  $VH_{on}$  threshold and the flag is released. See [Section 7.11 on page 35](#) for indication on how the failure flags can be released.

When VL voltage goes over the  $VL_{off}$  threshold the output buffer goes in “safe state” and the UVLOL status flag is forced high. If the UVLOlatch bit in the CFG4 register is set low (default), the UVLOL status flag is released when VL voltage goes below the  $VL_{on}$  threshold and the device returns to normal operation.

Otherwise the UVLOL flag is latched and the device remains in “safe state” until the VL voltage goes below the  $VL_{on}$  threshold and the flag is released. See [Section 7.11](#) for indication on how the failure flags can be released.

Overvoltage protection is available on both VH and VL supply pins. Both OVLO protections can be disabled by setting the proper value in the CFG4 register.

When the VH voltage goes over the  $OV_{VHoff}$  threshold the output buffer goes in “safe state” and the OVLOH status flag is forced high. The OVLOH flag is latched and the device remains in “safe state” until VH voltage goes below the overvoltage threshold and the flag is released. See [Section 7.11](#) for indication on how the failure flags can be released.

When VL voltage goes over the  $OV_{VLoff}$  threshold the output buffer goes in “safe state” and the OVLOL status flag is forced high. The OVLOL flag is latched and the device remains in “safe state” until VH voltage goes below the overvoltage threshold and the flag is released. See [Section 7.11](#) for indication on how the failure flags can be released.

## 7.5 Thermal warning and shutdown protection

The device provides a thermal warning and a thermal shutdown protection.

When junction temperature reaches the  $T_{WN}$  temperature threshold the TWN flag in the STATUS1 register is forced high. The TWN flag is released as soon as the junction temperature is lower than  $T_{WN} - T_{hys}$ .

When junction temperature reaches the  $T_{SD}$  temperature threshold, the device is forced in "safe state" and the TSD flag in the STATUS1 register is forced high. The device operation is restored and the TSD flag is released as soon as the junction temperature is lower than  $T_{SD} - T_{hys}$ .

## 7.6 Desaturation protection

This feature allows implementing an overload protection for the IGBT. The DESAT pin monitors the  $V_{CE}$  voltage of the IGBT while it is on, and if the protection threshold is reached, the IGBT is turned off.

When the IGBT is off (GOFF output is activated) the DESAT pin is kept low internally and the external blanking capacitor connected to the DESAT pin is discharged (the internal current generator is fully switched off and the switch between DESAT and GNDISO pins is turned on).

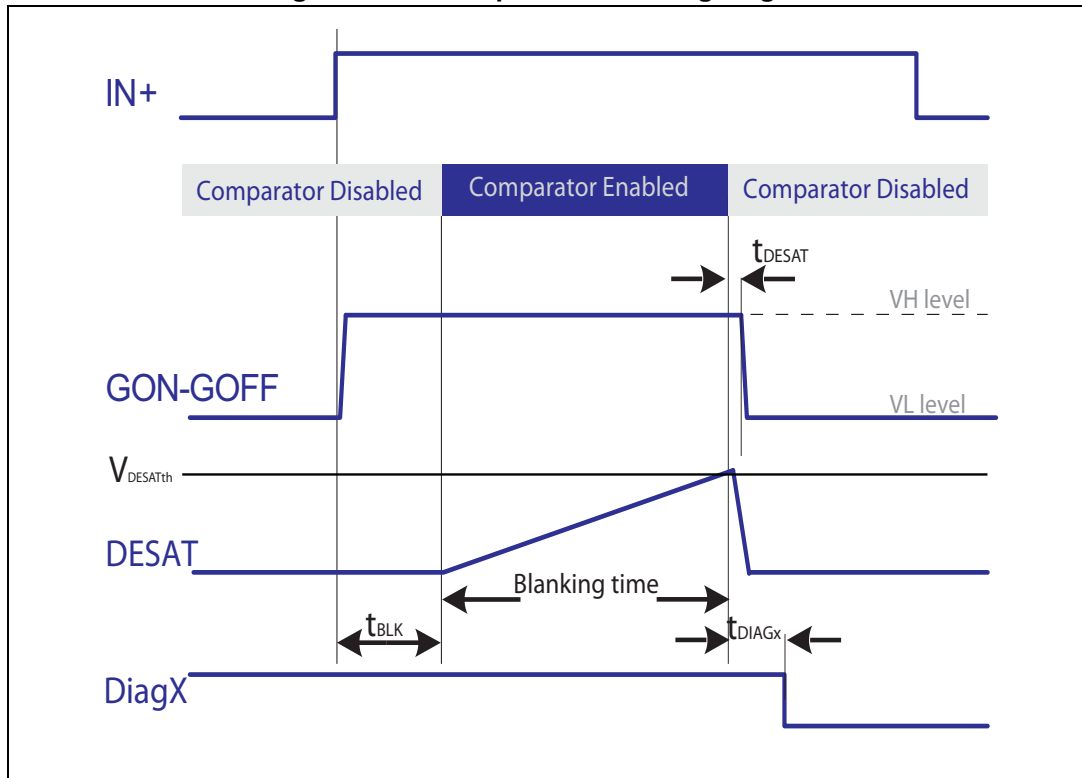
When the GON output is activated the switch between DESAT and GNDISO pins is turned off and an internal programmable current generator ( $I_{DESAT}$ ) starts charging the external blanking capacitor after a fixed blanking time  $t_{BLK}$ .

If a desaturation event occurs the  $V_{CE}$  voltage increases and the voltage at the DESAT pin reaches the desaturation threshold  $V_{DESATth}$ : the DESAT comparator output is set, the device is forced in "safe state" and the DESAT flag is forced high and latched.

The DESAT comparator is not active when the external IGBT is off or after desaturation detection (see [Figure 11](#)).

Both the  $V_{DESATth}$  threshold and the  $I_{DESAT}$  blanking current are programmable through the SPI.

Figure 11. DESAT protection timing diagram



A deglitch filter is applied to the DESAT pin. Each pulse exceeding the  $V_{DESATth}$  for a time shorter than  $t_{DESfilter}$  value shall not trigger the protection.

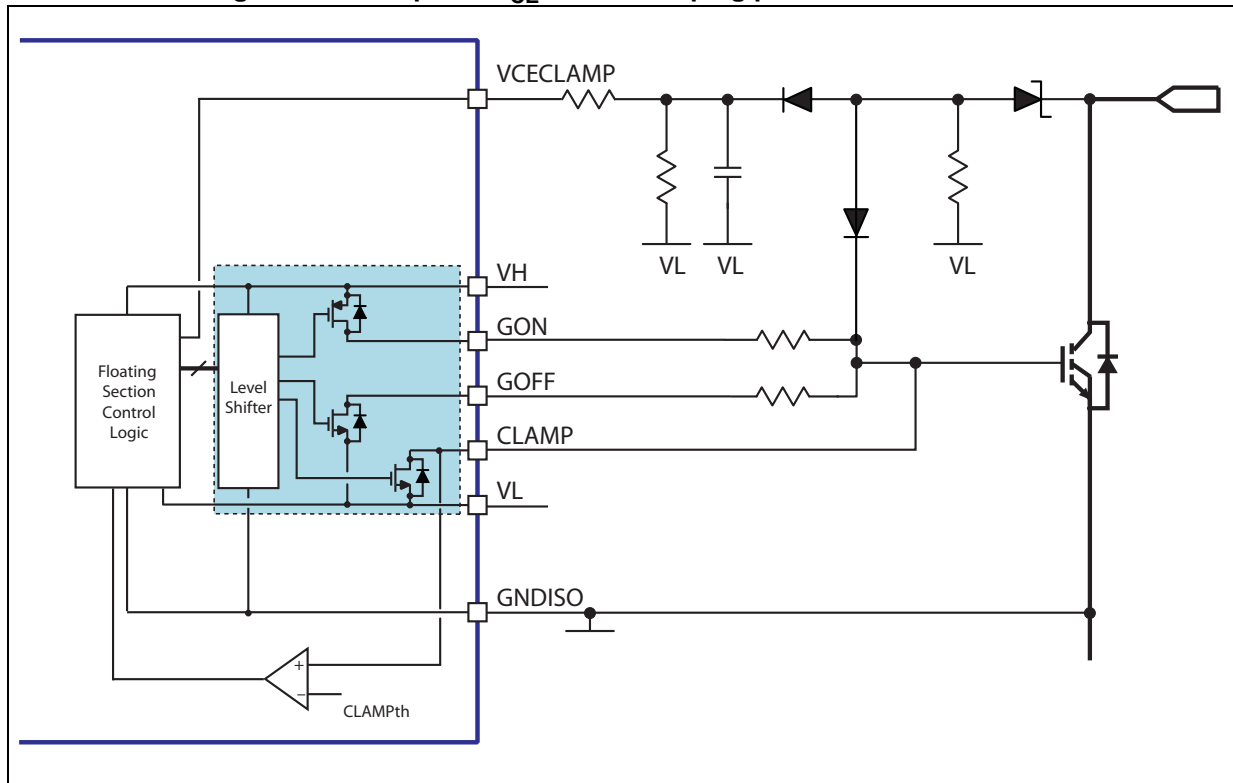
### 7.7 V<sub>CE</sub> active clamping protection

This protection is used to actively clamp the drain/collector overvoltage spikes during the MOSFET/IGBT turn-off. This feature allows using low turn-off resistor values leading lower turn-off losses, thus increasing efficiency, while limiting the maximum turn-off spike on the collector (or drain) within safe limits.

The direct feedback of the collector voltage to the device can for example be made via an element with avalanche characteristics such as a TVS. If the VCE voltage exceeds the breakdown voltage of the TVS, the  $V_{VCECLth}$  threshold voltage on the VCECLAMP is reached and the IC actively slows down the power switch turn-off to keep a safe condition.

The active limiting of the driver's turn-off current strongly reduces the current flowing through the TVS, thus preventing it from operating in overstressing conditions.

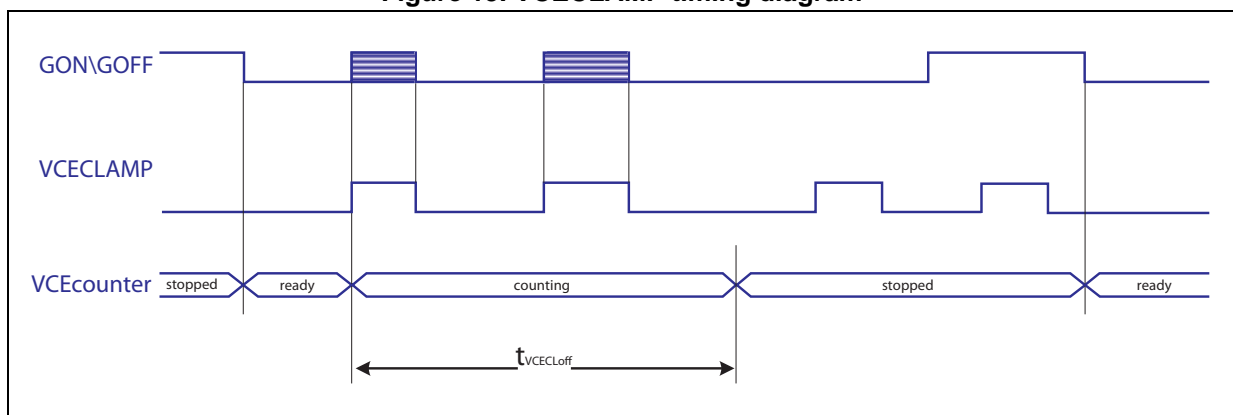
Figure 12. Example of  $V_{CE}$  active clamping protection connection



When the VCECLAMP is activated during the turn-off phase a watchdog timer starts inside the driver. This timer allows the VCECLAMP pin to act on the driver's output status for a  $t_{VCEClOff}$  time maximum. After that time has expired, the driver continues the normal turn-off ignoring the VCECLAMP pin status. This assures that the protection is only acting to clamp inductive  $V_{CE}$  spikes during the turn-off.

The timer is reset and the VCECLAMP protection is enabled again at the beginning of the following turn-off sequence.

Figure 13. VCECLAMP timing diagram



The VCECLAMP pin is masked and has no effect on the driver's outputs status when the external MOSFET/IGBT is on.

The  $V_{CE}$  active clamping protection can be disabled connecting the VCECLAMP pin to VL.



## 7.8 SENSE overcurrent protection

This function is suitable in applications in which it is possible to measure the load current through the use of a shunt resistor, or in applications that use IGBTs with the current sense pin available. The load current (or a fraction of it in case SenseFETs are used) is converted to voltage by an external shunt resistor and is fed to the SENSE pin (comparator input).

When an overcurrent event occurs the sense voltage reaches the  $V_{SENSEth}$  threshold, the device is forced in “safe state” and the SENSE status flag is forced high and latched.

The  $V_{SENSEth}$  threshold is programmable through the SPI (refer to [Section 9.2.2 on page 55](#)).

## 7.9 Miller clamp function

The Miller clamp function allows the control of the Miller current during the power stage switching in half-bridge configurations. When the external power transistor is in the OFF state, the driver operates to avoid the induced turn-on phenomenon that may occur when the other switch in the same leg is being turned on, due to the  $C_{gc}$  capacitance.

During the turn-off period the gate of the external switch is monitored through the CLAMP pin.

The CLAMP switch is activated when gate voltage goes below the voltage threshold  $V_{CLAMPth}$ , thus creating a low impedance path between the switch gate and the VL pin.

This function can be disabled setting low the CLAMP\_EN bit in the CFG5 register (high by default).

## 7.10 2-level turn-off function

If an overcurrent event happens, a large voltage overshoot exceeding  $V_{CE}$  absolute ratings may occur across the power switch during the turn-off, due to the parasitic stray inductances.

The 2-level turn-off function (2LTO) allows the reduction of the stressing overvoltage experienced by the power component in overcurrent condition by switching off the external power in two phases.

In the first phase the GOFF voltage is actively forced to a programmable value  $V_{2LTOth}$ ; after a programmable delay  $t_{2LTOtime}$  the GOFF is forced to VL to complete the gate turn-off.

This allows to slow down the critical part of the turn-off transient, that may induce the overvoltage spikes.

The voltage level  $V_{2LTOth}$  and duration  $t_{2LTOtime}$  of the intermediate off-level are programmable through the SPI.

It is possible to program when this feature takes place, refer to the following paragraphs.

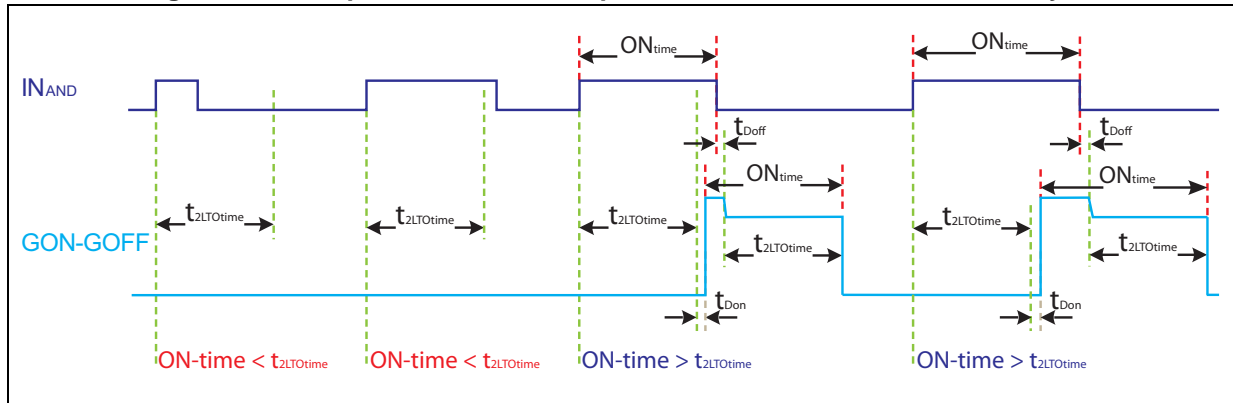
### 7.10.1 Always

The 2LTO is performed at each turn-off transition ( $2LTO\_EN = '1'$ ).

When 2LTO is used at each transition the minimum on or off pulse width is determined by 2LTO time. Some sample waveforms are given in [Figure 14](#) and [Figure 15](#), where  $IN_{AND}$  represents the condition:  $\langle IN+ = 'H'$  and  $IN- = 'L' \rangle$ .

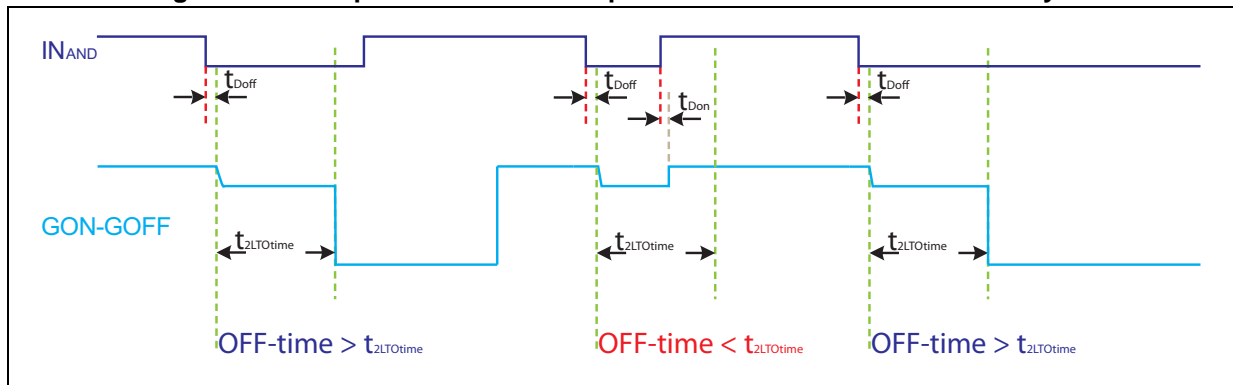
If a turn-on pulse is shorter than  $t_{2LTOtime}$  it shall be ignored; turn-on pulses longer than  $t_{2LTOtime}$  will determine a delay in the turn-on equal to  $t_{2LTOtime}$  (see [Figure 14](#)).

**Figure 14. Example of short turn-on pulses when 2LTO occurs at each cycle**



When a turn-off pulse is detected the turn-off procedure starts immediately by forcing the  $V_{2LTOth}$  voltage on the GOFF pin. If the duration of the turn-off pulse is shorter than  $t_{2LTOtime}$  the turn-off sequence is aborted by setting GOFF in high impedance and turning GON on again (see [Figure 15](#)).

**Figure 15. Example of short turn-off pulse when 2LTO occurs at each cycle**



When the 2LTO is used at each cycle, any event that forces the device to enter in “safe state” generates a driver switch off performing a 2LTO sequence.

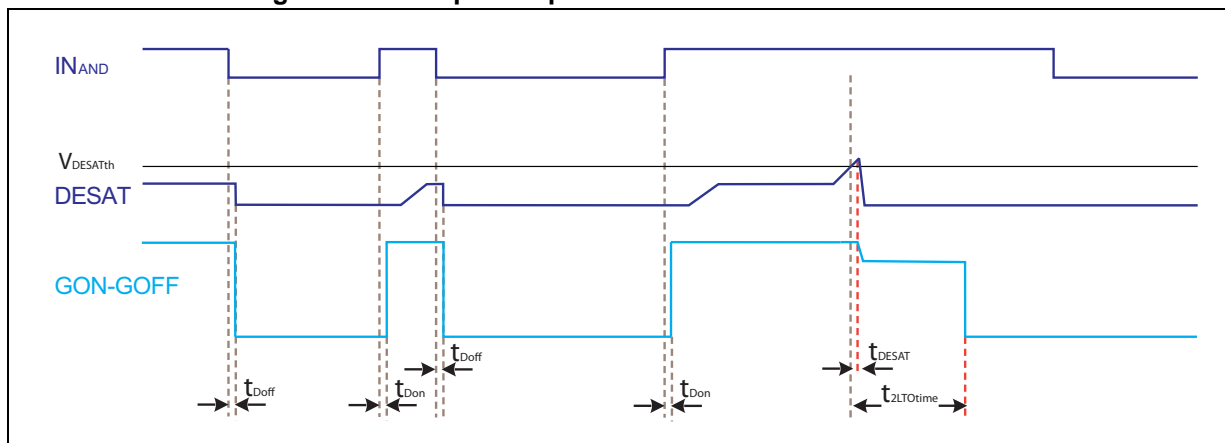
### 7.10.2 Fault

The 2LTO is performed only after a desaturation or overcurrent event ( $2LTO\_EN = '0'$ ). In such cases the device enters in “safe state” until the failure flag is released. See [Section 7.11](#) for indication on how the failure flags can be released.

This configuration overrides some drawbacks of using the 2LTO at each turn-off, such as the minimum pulse width equal to  $t_{2LTOtime}$  and the turn-on delay needed to avoid duty cycle distortion.

With this configuration the turn-off is only slowed down in case of desaturation or overcurrent events.

Figure 16. Example of operation with 2LTO in “Fault” mode



### 7.10.3 Never

The 2LTO function is disabled ( $2LTOtime = 0x0$ ). In this case a standard turn-off sequence is used (directly lowering the gate voltage from VH to VL) also in case of desaturation or sense overcurrent events.

## 7.11 Failure management

The device provides advanced diagnostic through open drain outputs ( $\overline{DIAG1}/\overline{DIAG2}$ ) and internal status registers. The  $\overline{DIAG2}$  output shares the same pin of the IN- input (see [Figure 1 on page 8](#)); the diagnostic signal through the pin is enabled through the DIAG\_EN bit as described in [Section 7.1 on page 25](#).

Status registers (STATUS1, STATUS2 and STATUS3) provide failures and status information as listed in respective paragraphs.

$\overline{DIAG1}$  and  $\overline{DIAG2}$  pins can be programmed through the dedicated registers (DIAG1CFG and DIAG2CFG) to signal one or more failure conditions. The output value is the result of the NOR of the selected status bits: if one of the selected bits is high, the output is forced low.

Some of the failure conditions reported by the status registers are latched, i.e.: the flag is kept high even if the triggering condition is expired.

Different methods can be used to clear the failure flags contained in the status registers:

- Using the *ResetStatus* command**  
 The SD must be set low before giving this command, and must remain low until the end of the command's execution time.  
 This is the recommended method, because guarantees that status registers are only cleared by direct intervention of the MCU.

All flags in the StatusRegisters are released after a  $t_{desCS}$  time following the rise of the SPI CS.

- **Forcing low the  $\overline{SD}$  pin for at least  $t_{release}$**   
All the flags are released at the rising edge of the  $\overline{SD}$ . This mode is enabled at device's power-on, but it can be disabled by setting the SD\_FLAG configuration bit low during the configuration phase, and by doing this any possibility to clear a FLAG without direct intervention of the MCU is prevented. Even if the SD\_FLAG is set high, status registers are not cleared after the rising edge of the  $\overline{SD}$  if a configuration sequence is executed (StartConfig, StopConfig). This is done to avoid clearing errors that may have been generated during the configuration procedure.
- **Using HW reset** (see [Section 7.3 on page 29](#))  
In this case the device behaves as after power-up sequence.

In any case, if the failure condition is still present, the respective flag is not released.

Selected failures force the device in "safe state"; the device remains in this state until the relative status flags are released. Refer to [Table 49 on page 61](#), [Table 51 on page 62](#) and [Table 53 on page 63](#) for details.

The possibility to clear status registers by setting the  $\overline{SD}$  low allows operating the device also without using the SPI interface. In order to avoid an unintended clear of fault conditions it is recommended to disable this functionality by setting the SD\_FLAG = '0'.

## 7.12 Asynchronous stop command

The ASC pin allows to turn-on the GON output acting directly on the isolated driver logic and regardless of the status of the input pins IN+, IN- and  $\overline{SD}$ . This pin is active high.

The status of this pin is mirrored in the ASC bit present in the STATUS2 register.

The power supply of the isolated section must be present ( $V_H > V_{H_{on}}$ ).

In case UVLO on V<sub>H</sub> is not enabled, ASC function works for V<sub>H</sub> values within the recommended operating values.

This function works even if the VDD voltage is not available or is in UVLO condition.

The priority of such command is lower than that of DESAT and SENSE pins, so the ASC command is ignored in case of a desaturation or overcurrent fault. After such events the gate can be turned on again with a low-to-high transition of the ASC pin, or by clearing the fault condition (see [Section 7.11](#)).

## 7.13 Watchdog and echo

The isolated side provides a watchdog function in order to identify when it is no more able to communicate with the LV side. In this case the driver is automatically forced in "safe state" and the REGERRR flag is set.

When the LV side is in the standby mode, turned off or in hardware reset condition, the isolated side watchdog is still operative and the REGERRR flag is set.

The low voltage side provides a watchdog function in order to identify when it is no more able to communicate with the isolated side. In this case the REGERRL flag is set and the device is forced in "safe state".

An echo function is implemented in order to check that input commands toward the gate are correctly propagated to the driver's output. In case something should prevent the correct propagation of the command, the driver is able to detect this condition and will start a new communication (echo) in order to set the desired output state. This process has typical duration of 4  $\mu$ s.

## 7.14 Security check functions

The device allows verifying the gate and sense resistor connections and the functionality of SENSE and DESAT. This can be achieved through the following security checks:

- GON to gate path
- GOFF to gate path
- SENSE comparator
- SENSE resistor
- DESAT comparator

The check modes are enabled through a dedicated configuration register TEST1 (refer to [Section 9.2.9 on page 63](#)) and thus require entering in configuration mode.

Only one check mode at a time must be enabled. At the end of security check procedure, the TEST1 register must be set to 0x00 before running the device in normal mode.

It is recommended to clear the status register with the ResetStatus command before and after each check.

To prevent the  $\overline{SD}$  from clearing the STATUS flags, set the SD\_FLAG = '0' as described in [Section 7.11](#).

### 7.14.1 GON to gate path check

The purpose of this security check is to verify the path integrity including the driver's GON output, the GON (turn-on) gate resistor, the power switch gate and the CLAMP pin (see [Figure 17](#)).

To perform this test, the following procedure has to be followed:

- Set  $\overline{SD}$  = low
- Send StartConfig command
- Set GONCHK = '1'
- Send StopConfig command
- Wait  $t_{Gchk}$
- Read TSD flag
  - TSD = '0' → OK ( $V_{CLAMP} > V_{Gchk}$ )
  - TSD = '1' → FAIL ( $V_{CLAMP} < V_{Gchk}$ )

Please note that during all the time the check is enabled the gate will be forced high (GON turned on) regardless the  $\overline{SD}$  pin level. The user test routine has to take into account this behavior.

In any case, when GONCHK = '1', the protections SENSE and DESAT, if enabled, will continue to operate protecting the power switch regardless the  $\overline{SD}$  pin.

### 7.14.2 GOFF to gate path check

The purpose of this security check is to verify the path integrity including the driver's GOFF output, the GOFF (turn-off) gate resistor, the power switch gate and the CLAMP pin (see [Figure 17](#)).

To perform this test, the following procedure has to be followed:

- Set  $\overline{SD}$  = low
- Send StartConfig command
- Set GOFFCHK = '1'
- Send StopConfig command
- Wait  $t_{Gchk} + t_{GATE\_GOFFchk}$
- Read DESAT flag
  - DESAT = '0' → OK ( $V_{CLAMP} < V_{CLAMPth}$ )
  - DESAT = '1' → FAIL ( $V_{CLAMP} > V_{CLAMPth}$ )

During the check a small current  $I_{GOFFchk}$  will be sourced from the CLAMP pin while GOFF is on keeping the gate low through the turn-off gate resistor.

To ensure the check result, some applicative conditions have to be verified:

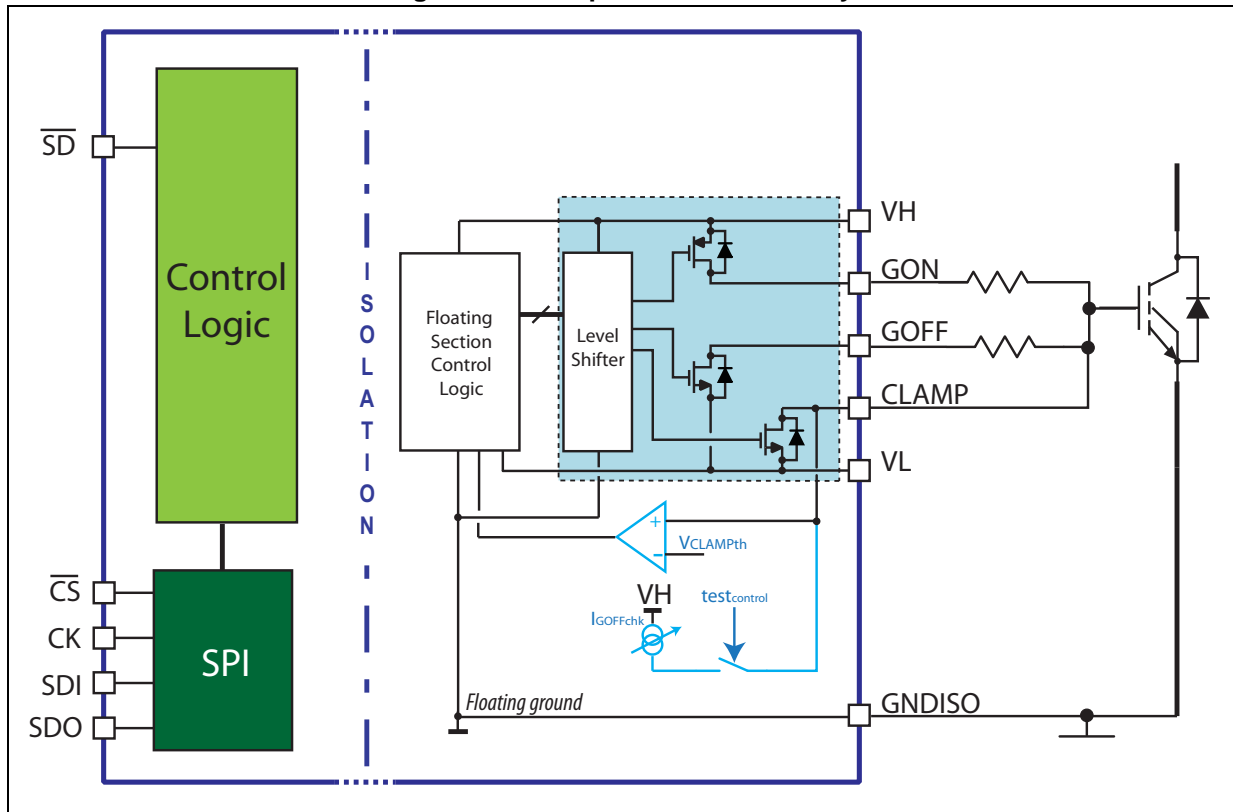
- The bleeding resistor, sometimes present between the gate and source in the power switch, shall be higher than 8.2 kΩ.
- During the test, the power switch gate shall have the time to be charged up to  $V_{CLAMPth}$  by  $I_{GOFFchk}$ . In case no bleeding resistor is present, this time can be roughly computed as:

$$t_{GATE\_GOFFchk} \approx C_{GATE} * (V_{CLAMPth} - V_L) / I_{GOFFchk}$$

If a bleeding resistor is present or an additional push-pull circuit has been added, the time has to be computed with the adequate corrective factors.

If the check fails due to the lack of the GOFF resistor, the power switch gate will gradually rise up to  $V_H$  with no protections of SENSE nor DESAT. The user test routine shall consider this behavior.

Figure 17. Gate paths check circuitry



### 7.14.3 SENSE comparator check

The purpose of this security check is to verify the functionality of the sense comparator.

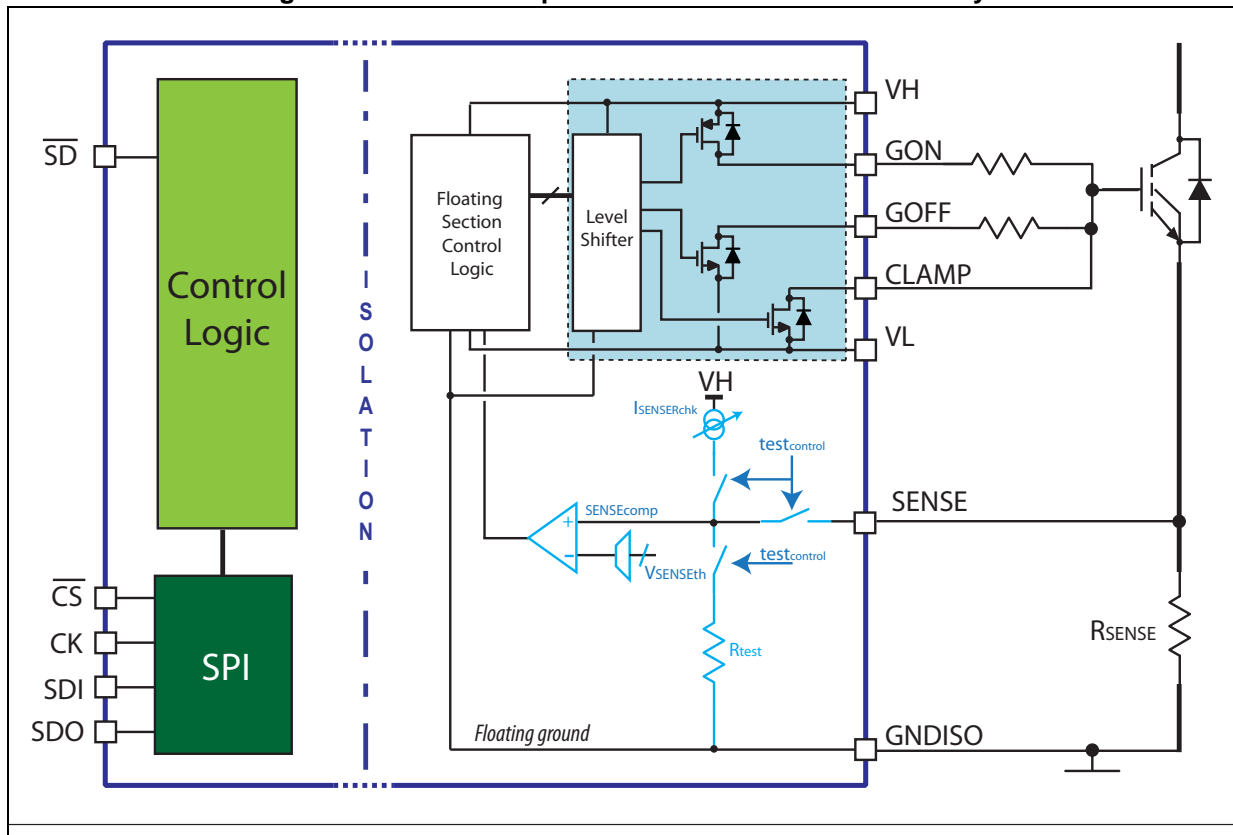
To enable this check, it is required to set SNSCHK = '1' and SENSE\_EN = '1'.

When this check is enabled the switch in series to the SENSE pin is open (see [Figure 18](#)); a SENSE fault (STATUS1 register) should be reported within  $t_{SENSEchk}$ , otherwise the SENSE comparator operation is compromised.

- $V_{SENSEcomp} > V_{SENSEth}$  → comparator OK → SENSE = '1'
- $V_{SENSEcomp} < V_{SENSEth}$  → comparator FAIL → SENSE = '0'

The SENSE fault generated by this test is latched and shall be cleared accordingly.

Figure 18. SENSE comparator and resistor check circuitry





#### 7.14.4 SENSE resistor check

The purpose of this security check is to verify the connection between the device and the sense shunt resistor and to verify the optional sense resistor filter network is not open.

To perform this test, the following procedure has to be followed:

- Set  $\overline{SD}$  = low
- Send StartConfig command
- Set SENSE\_EN = '1'
- Set SNSCHK = '1'
- Send StopConfig command
- Wait  $t_{Rchk} + t_{SENSEchk}$
- Read SENSE flag
  - SENSE = '0' → OK ( $V_{SENSE} < V_{SENSEth}$ )
  - SENSE = '1' → FAIL ( $V_{SENSE} > V_{SENSEth}$ )

During the check a small current  $I_{SENSEchk}$  is sourced from the SENSE pin (see [Figure 18](#)). If the sense resistor is not present or floating, SENSE pin voltage will rise and once  $V_{SENSEth}$  is exceeded, a SENSE fault will be reported in the STATUS1 register within  $t_{Rchk}$ .

To ensure the check result, the following condition has to be verified:

- The SENSE flag read has to be delayed of  $t_{SENSEchk}$ , which is the time the customer filtering network and/or the power switch gate takes to reach  $V_{SENSEth}$  by the  $I_{SENSEchk}$  current.

### 7.14.5 DESAT comparator check

The purpose of this security check is to verify the functionality of the desaturation comparator.

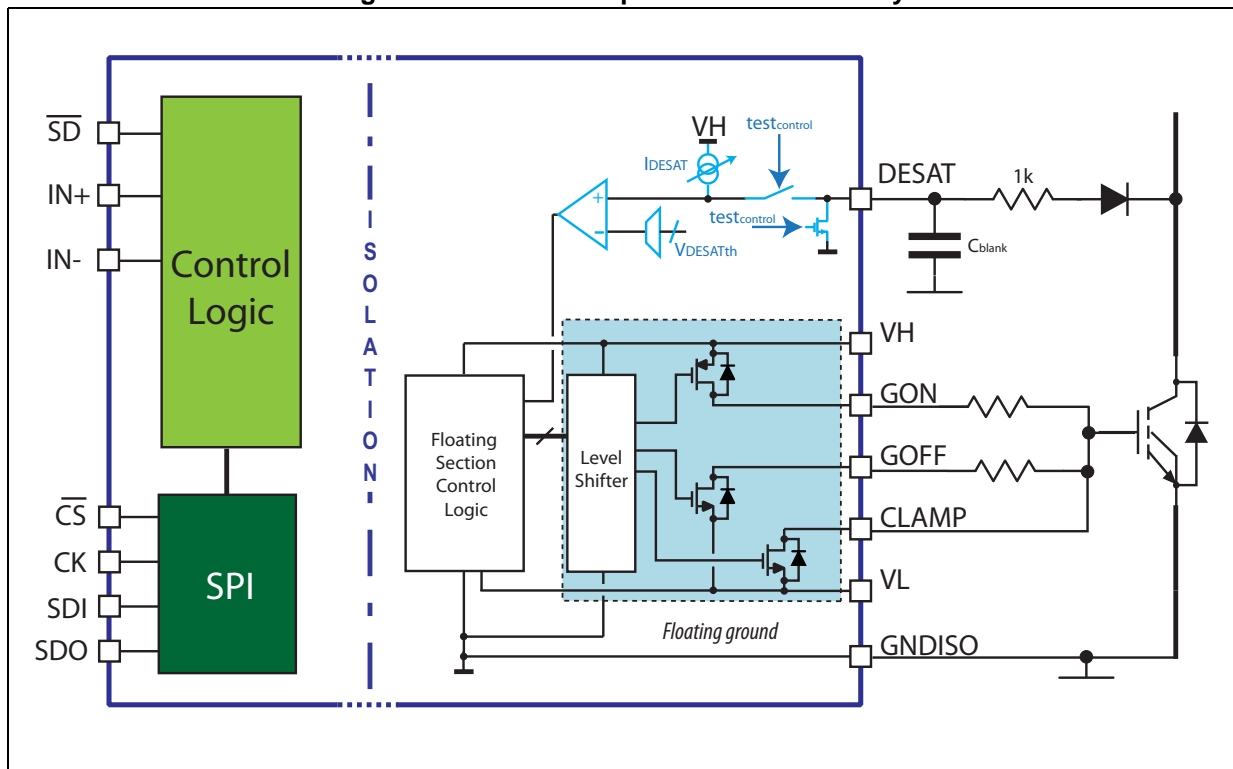
To perform this test, the following procedure has to be followed:

- Set  $\overline{SD}$  = low
- Send StartConfig command
- Set DESAT\_EN = '1'
- Set DESCHK = '1'
- Send StopConfig command
- Set  $\overline{SD}$  = high
- Wait 3  $\mu$ s
- Apply at the inputs a gate turn on pulse longer than 500 ns
- Read DESAT flag
  - DESAT = '1'  $\rightarrow$  OK ( $V_{DESATcomp} > V_{DESATth}$ )
  - DESAT = '0'  $\rightarrow$  FAIL ( $V_{DESATcomp} < V_{DESATth}$ )

During this test GON is first turned on and then turned off as soon the test succeeds. In case the test should fail, the output remains on as long as the input signal remains high.

At the end of the check the DESAT fault remains set (it is latched), and it has to be cleared.

Figure 19. DESAT comparator check circuitry



## 7.15 Register corruption protection

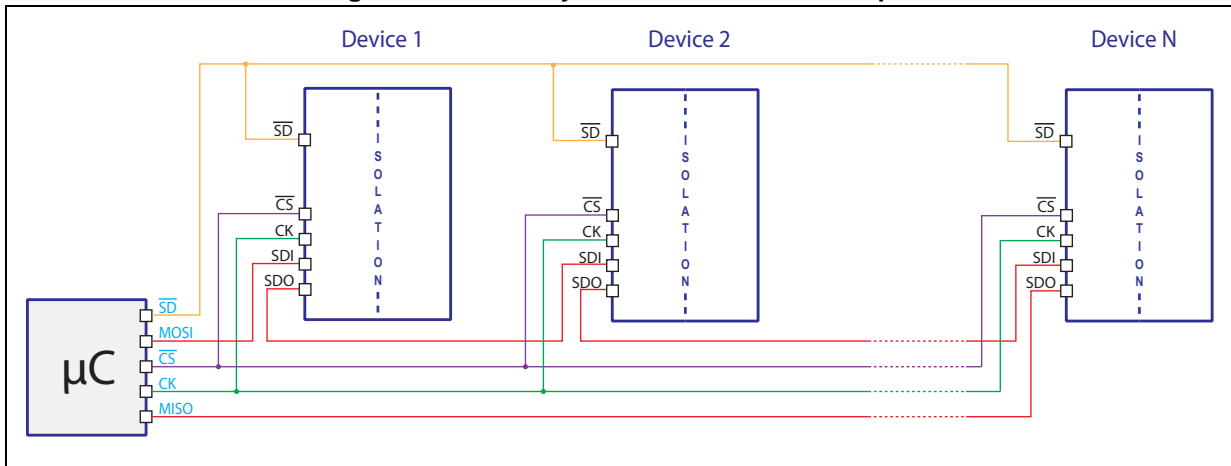
All the configuration registers are protected against content corruption.

If the value of a local register is changed without a proper command is received (*WriteReg*, *ResetStatus* or *GlobalReset*), the REGERRL flag is set low and the device is forced in “safe state”.

If the value of a remote register is changed without a proper command is received (*WriteReg* or *GlobalReset*), the REGERRR flag is set low and the device is forced in “safe state”.

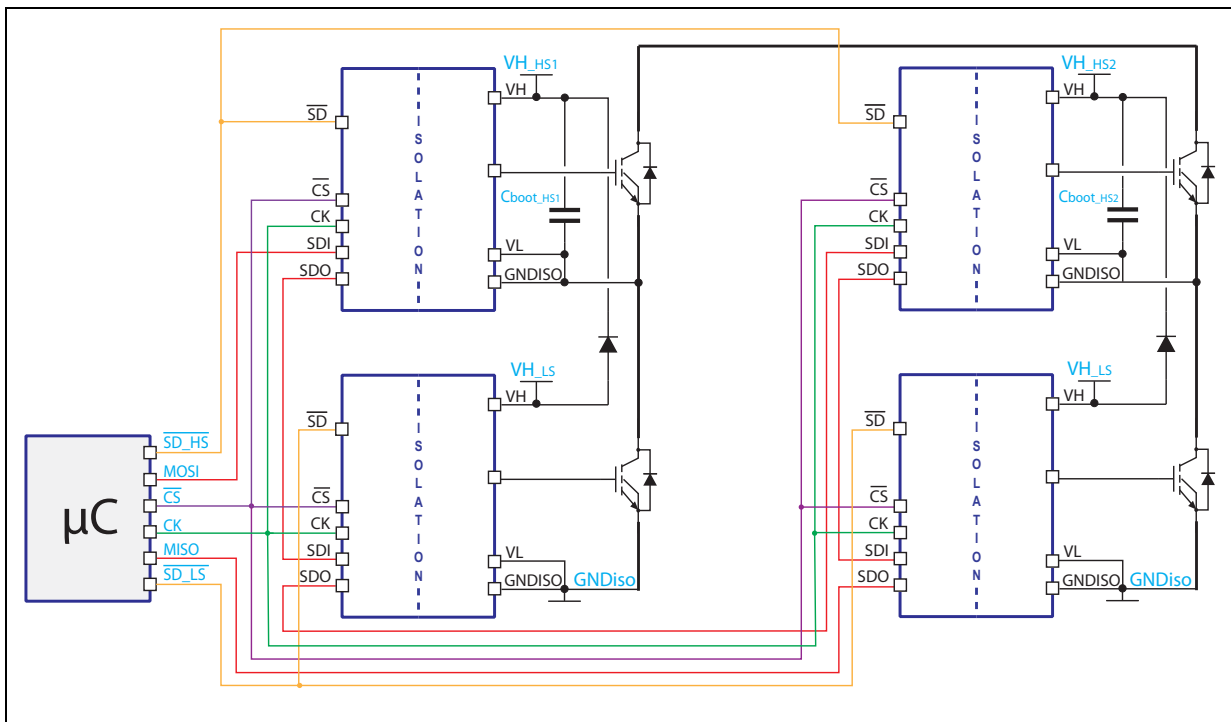


Figure 21. SPI daisy chain connection example



In case a bootstrap capacitor and a diode are used to generate the  $V_H$  supply voltage for the high-side drivers, it is recommended to have one dedicated  $SD$  line for all of the high-side drivers and another dedicated  $SD$  line for all of the low-side drivers. An example of such topology is shown in [Figure 22](#).

Figure 22. SPI daisy chain connection example when bootstrap technique is used for high-side drivers



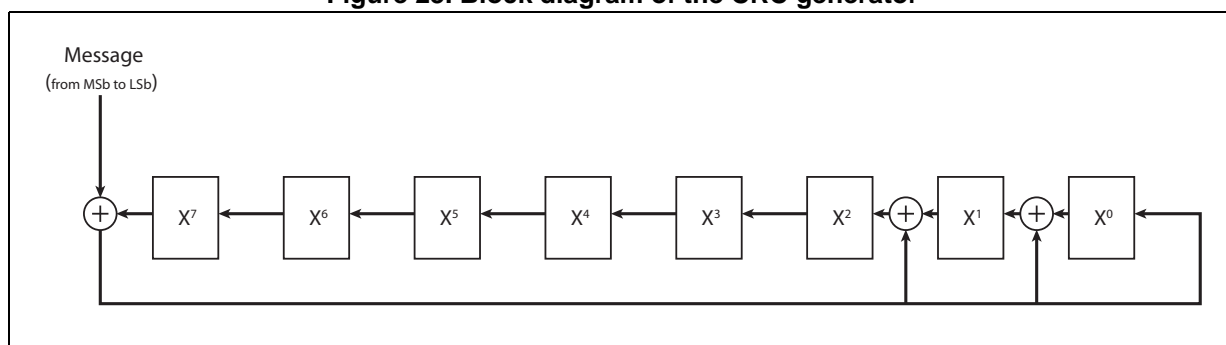
## CRC protection

All the command and data bytes have to be followed by a CRC code. If the CRC\_SPI bit is set high, this code is used to check the data byte is correct, otherwise the CRC byte is ignored. In this case the CRC byte must be transmitted by the host, but its value is unimportant.

A failure on the CRC check causes the respective data byte is ignored and the SPI\_ERR flag is set high.

The polynomial generator of the CRC code is  $X^8 + X^2 + X + 1$  corresponding to the block diagram in [Figure 23](#).

**Figure 23. Block diagram of the CRC generator**



The host must transmit to the device the inverted CRC code computed using the following procedure:

- Initialize CRC to all 1
- Start the calculation from the most significant bit of the message
- Invert the CRC result

In case of a WriteReg command, the CRC of the data byte (i.e.: the new register value) must be calculated initializing the computation system to the CRC of the command byte (i.e.: the CRC is calculated on a 16-bit message composed by the command + data byte). This way a data byte cannot be accepted as a command byte and vice-versa. Some examples are listed in [Table 11](#).

The device always transmits a response byte followed by a CRC computed using the same polynomial generator ( $X^8 + X^2 + X + 1$ ). The CRC byte transmitted by the device is not inverted.

If no response is required, the word returned by the device has no meaning and it should be discarded. Some examples are listed in [Table 12](#).

**Table 11. CRC byte examples (from host to device)**

Command	Command byte	Command CRC	Data byte	Data CRC
StopConfig	0x3A	0xAA	N.A.	N.A.
WriteReg(CFG1, 0x20)	0x8C	0xA1	0x20	0x82
WriteReg(CFG5, 0x06)	0x99	0xCA	0x06	0x66
ResetStatus	0xD0	0x32	N.A.	N.A.
ReadReg(CFG3)	0xBE	0x3F	N.A.	N.A.

Table 12. CRC byte examples (from device to host)

Data byte	Data CRC
0x00	0xF3
0xEA	0x6B
0xF5	0x36
0x2A	0x25

# 9 Programming manual

## 9.1 SPI commands

The commands summary is given in [Table 13](#).

**Table 13. SPI commands**

Command mnemonic	Command value								Action	Notes
	0	0	1	0	1	0	1	0		
StartConfig	0	0	1	0	1	0	1	0	Device configuration start	Enter CFG mode SD low only
StopConfig	0	0	1	1	1	0	1	0	Device configuration/check completed	Leave CFG mode SD low only
NOP	0	0	0	0	0	0	0	0	No operation	
WriteReg	1	0	0	A	A	A	A	A	Write AAAAA register	CFG mode only
ReadReg	1	0	1	A	A	A	A	A	Read AAAAA register	
ResetStatus	1	1	0	1	0	0	0	0	Reset all the status registers	SD low only
GlobalReset	1	1	1	0	1	0	1	0	Global reset	CFG mode only
Sleep	1	1	1	1	0	1	0	1	Device enters in standby mode	SD low only

### 9.1.1 StartConfig and StopConfig commands

**Table 14. StartConfig command synopsis**

Byte	1	2
To device	0010 1010	1101 1010 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

**Table 15. StopConfig command synopsis**

Byte	1	2
To device	0011 1010	1010 1010 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

Device parameters are configured by writing configuration values in configuration registers (CFGx and DIAGxCFG), which is only possible by entering in configuration mode.

To switch the device to the configuration mode the *StartConfig* command must be sent. This command is accepted when the SD line is low only. If the command has been correctly received and interpreted, the IC registers writing is enabled.

The SD pin must be kept low during the whole configuration procedure, which is terminated by the *StopConfig* command. If the SD pin is raised during the configuration procedure the device immediately quits the configuration mode causing a fault error indicated by the REGERRL and REGERRR bits. In this case all the changes operated on device configuration are undone and the previous configuration is restored.



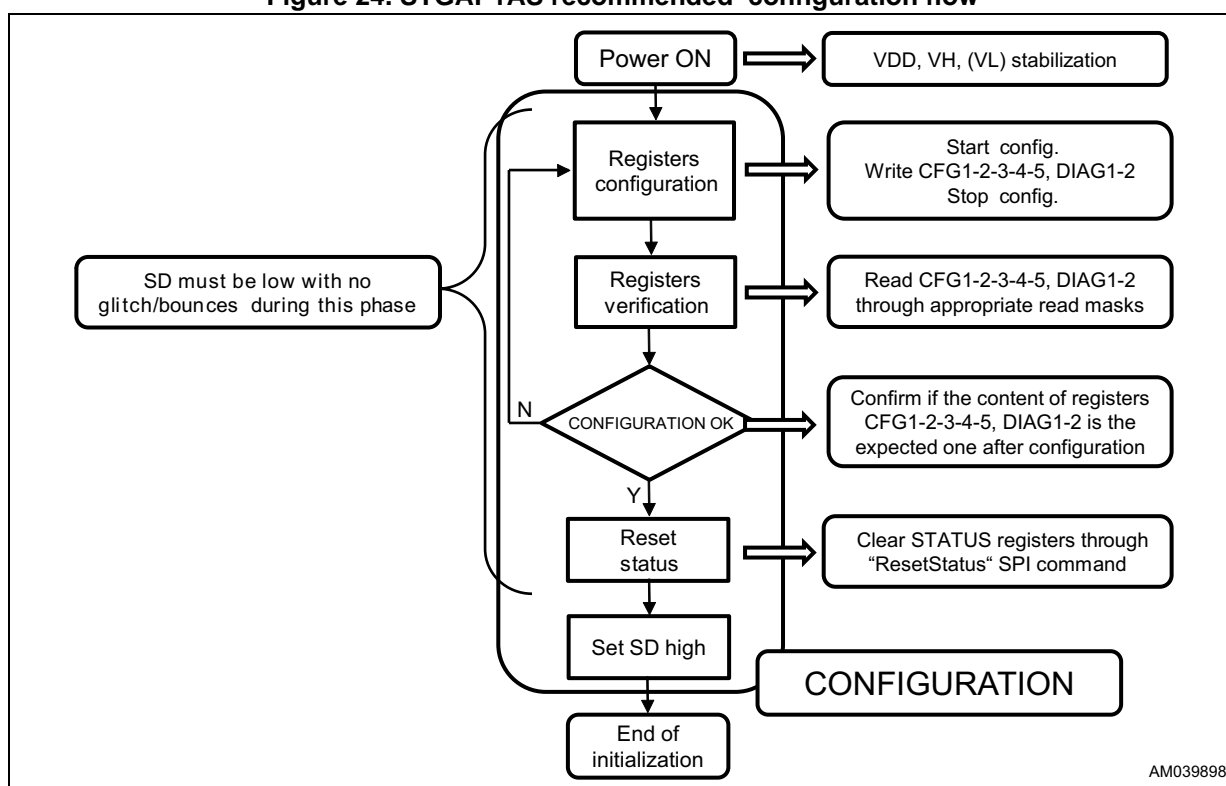
At the end of the device setup the *StopConfig* command has to be sent in order to quit the configuration mode and make all changes effective.

Configuration sequence must be repeated every time the power supply on either side (VDD or VH) is removed and then restored.

- VDD falling below critical value will result in the REGERRL flag being set in status registers after that the proper VDD level is restored.
- VH falling below critical value will result in the REGERRR flag being set in status registers.

After that all supply voltages are supplied and stable, the configuration process can be executed. The flow chart shown in *Figure 24* is recommended for the configuration. In this way it will be possible to check that the desired configuration has been correctly stored in the device at the end of the configuration sequence.

**Figure 24. STGAP1AS recommended configuration flow**



### 9.1.2 WriteReg command

**Table 16. WriteReg command synopsis**

Byte	1	2	3	4
To device	100A AAAA <sup>(1)</sup>	CCCC CCCC <sup>(2)</sup>	DDDD DDDD <sup>(3)</sup>	KKKK KKKK <sup>(4)</sup>

1. The command byte where AAAAA is the address of the target register.
2. The CRC byte of the command, if the CRC check is disabled this byte is ignored.
3. Data to be written into the target register.
4. The CRC byte of the command and data, if the CRC check is disabled this byte is ignored.

The device register can be written through the *WriteReg* command when the device is set in the configuration mode only (refer to [Section 9.1.1](#)), otherwise the write command is ignored and the SPI\_ERR flag is forced low.

The *WriteReg* command is followed by the data to be written into the target register. The CRC code following the data is based on both command and data bytes. In this way, in case of communication error, a data byte cannot be decoded as a command and vice-versa (refer to [Section : CRC protection on page 46](#)).

### 9.1.3 ReadReg command

**Table 17. ReadReg command synopsis**

Byte	1	2	3 <sup>(1)</sup>	4
To device	101A AAAA <sup>(2)</sup>	CCCC CCCC <sup>(3)</sup>	0000 0000	CCCC CCCC <sup>(4)</sup>
From device	0000 0000	0000 0000	DDDD DDDD <sup>(5)</sup>	KKKK KKKK <sup>(6)</sup>

1. Proper time have to be waited in order to allow the device to prepare the data.
2. The command byte where AAAAA is the address of the target register.
3. The CRC byte of the command, if the CRC check is disabled this byte is ignored.
4. The CRC byte of the NOP command.
5. Data read from the target register.
6. The CRC byte of the data.

All the registers of the device can be read anytime, and this requires two accesses ( $\overline{CS}$  must be asserted LOW and HIGH twice). In the first access the SPI host issues the ReadReg command (including the register address) and the CRC of the first byte, which will be ignored if SPI CRC is not enabled. After the command is received and decoded by the device, the register value and the respective CRC code is prepared for the transmission. The CRC polynomial used by the device during the transmission is different from the one used by the host, but the CRC code is not inverted before transmission (refer to [Section : CRC protection](#)).

The time required to obtain the reading result changes according to the side where the register is located. The reading of a local register (low voltage side) is available in 800 ns. The reading of a remote register (isolated side), if no communication error occurs between the two sides of the device, is available in 30  $\mu$ s.

After the read result is ready it is stored in the SPI output buffer, and the host MCU will receive it as soon as it will send a new SPI command. Any command can be used for this purpose, including a NOP or the ReadReg command for the next register to be read.

Some status and configuration registers contain a reserved bit whose content is not predictable. In order to clearly identify the content of relevant information, the value read from each register should be masked with the appropriate masking code (see “Mask code” in [Table 23](#)).

### 9.1.4 ResetStatus and GlobalReset commands

**Table 18. ResetStatus command synopsis**

Byte	1	2
To device	1101 0000	0011 0010 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

The *ResetStatus* command is a specific reset command which acts on all status registers releasing all the latched flags. The command is executed only when the  $\overline{SD}$  input is low, otherwise the SPI\_ERR flag is forced low.

**Table 19. GlobalReset command synopsis**

Byte	1	2
To device	1110 1010	1001 0100 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

The *GlobalReset* command reset all the registers to the default and releases all the failure flag (if latched). It can be sent when the device is in the configuration mode only, otherwise the command is ignored and the SPI\_ERR flag is forced low.

### 9.1.5 Sleep command

**Table 20. Sleep command synopsis**

Byte	1	2
To device	1111 0101	1100 1001 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

The command forces the device to switch in standby mode within a  $t_{\text{sleep}}$  period. The command is executed only when the  $\overline{SD}$  pin is low, if the  $\overline{SD}$  pin is high the command is ignored and the SPI\_ERR flag is forced low.

Refer to [Section 6.4 on page 24](#) for the description of the standby mode.

### 9.1.6 NOP command

**Table 21. NOP command synopsis**

Byte	1	2
To device	0000 0000	0000 1100 <sup>(1)</sup>

1. The CRC byte of the command, if the CRC check is disabled this byte is ignored.

The command does not modify the device status and does not generate any answer.

## 9.2 Registers and flags description

All device features can be configured through a set of 8-bit long registers.

There are three different types of registers:

- Local registers are located on the low voltage side
- Remote registers are located on the isolated side
- Shared registers are located both on the low voltage and isolated side and the value of the two copies is kept synchronized.

A map of the user registers is shown in [Table 22](#).

**Table 22. Registers map**

Name	Side (1)	Structure							
		[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]
CFG1	L	CRC_SPI	UVLOD_EN	SD_FLAG	DIAG_EN	DTset		INfilter	
CFG2	R	SENSEth		DESATcur		DESATth			
CFG3	R	2LTOth				2LTOtime			
CFG4	R	-	-	OVLO_EN	UVLOlatch	VLONth		VHONth	
CFG5	R	-	-	-	-	2LTO_EN	CLAMP_EN	DESAT_EN	SENSE_EN
STATUS1	L	OVLOH	OVLLOL	DESAT	SENSE	UVLOH	UVLOL	TSD	TWN
STATUS2	L	-	-	-	-	-	REGERRR	ASC	-
STATUS3	L	-	-	-	DT_ERR	SPI_ERR	REGERRL	OVLOD	UVLOD
TEST1	R	-	-	-	GOFFCHK	GONCHK	DESCHK	SNSCHK	RCHK
DIAG1CFG	L	DIAG1_7	DIAG1_6	DIAG1_5	DIAG1_4	DIAG1_3	DIAG1_2	DIAG1_1	DIAG1_0
DIAG2CFG	L	DIAG2_7	DIAG2_6	DIAG2_5	DIAG2_4	DIAG2_3	DIAG2_2	DIAG2_1	DIAG2_0

1. R: remote (isolated side), L: local (low voltage side).

Table 23. Registers access

Name	Address	Mask code
CFG1	0x0C	0xFF
CFG2	0x1D	0xFF
CFG3	0x1E	0xFF
CFG4	0x1F	0x3F
CFG5	0x19	0x0F
STATUS1	0x02	0xFF
STATUS2	0x01	0x06
STATUS3	0x0A	0x1F
TEST1	0x11	0x1F
DIAG1CFG	0x05	0xFF
DIAG2CFG	0x06	0xFF

### 9.2.1 CFG1 register (low voltage side)

The CFG1 register has the structure of [Table 24](#).

Table 24. CFG1 register

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	CRC_SPI	UVLOD_EN	SD_FLAG	DIAG_EN	DTset		INfilter	
Default/reset	0	0	1	0	00		00	

The CRC\_SPI bit enables the CRC check on the SPI communication protocol.

Table 25. CRC enable

CRC_SPI	SPI communication protocol CRC enable
0	Disabled
1	Enabled

The UVLOD\_EN bit enables the UVLO protection on VDD supply voltage.

Table 26. VDD supply voltage UVLO enable

UVLOD_EN	Supply voltage UVLOD enable
0	Disabled
1	Enabled

The SD\_FLAG bit sets the  $\overline{SD}$  pin functionality according to [Table 27](#). When the reset of the failure flags through the SD pin is enabled, keeping low the SD pin for at least  $t_{release}$  causes all the latched flags of the status registers to be released at the next SD rising edge.

**Table 27.  $\overline{SD}$  pin FAULT management**

SD_FLAG	$\overline{SD}$ pin functionality
0	$\overline{SD}$ pin do not reset STATUS registers
1	$\overline{SD}$ pin reset STATUS registers

The DIAG\_EN bit sets if the IN-/ $\overline{DIAG2}$  pin works as the input or open drain output according to [Table 28](#). Refer to [Section 7.1 on page 25](#) for details.

**Table 28. IN-/ $\overline{DIAG2}$  pin functionality**

DIAG_EN	IN-/ $\overline{DIAG2}$ pin functionality
0	The IN-/ $\overline{DIAG2}$ pin work as input
1	The IN-/ $\overline{DIAG2}$ pin work as open drain output

The DTset bits set the deadtime value.

**Table 29. Deadtime**

DTset [1 ... 0]	Deadtime value [ns]	-
0	0	Disabled
0	1	250
1	0	800
1	1	1200

The INfilter bits set the input deglitch time  $t_{deglitch}$  for the  $\overline{SD}$ , IN- and IN+ pins.

**Table 30. Input deglitch time**

INfilter [1 ... 0]	Input deglitch time value [ns]
0	0
0	1
1	0
1	1

## 9.2.2 CFG2 register (isolated side)

The CFG2 register has the structure of [Table 31](#).

**Table 31. CFG2 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	SENSEth			DESATcur		DESATth		
Default/reset	000			00		100		

The SENSEth bits set the SENSE comparator threshold according to [Table 32](#). Refer to [Section 7.8 on page 33](#) for details.

**Table 32. SENSE threshold**

SENSEth [2 ... 0]			SENSE threshold value [mV]
0	0	0	100
0	0	1	125
0	1	0	150
0	1	1	175
1	0	0	200
1	0	1	250
1	1	0	300
1	1	1	400

The DESATcurr parameter sets the current sourced by the DESAT pin according to [Table 33](#) and the DESATth parameter sets the DESAT comparator threshold according to [Table 34](#). Refer to [Section 7.6 on page 30](#) for details.

**Table 33. DESAT current**

DESATcur [1 ... 0]	DESAT current value [μA]	
0	0	250
0	1	500
1	0	750
1	1	1000

Table 34. DESAT threshold

DESATth [2 ... 0]			DESAT threshold value [V]
0	0	0	3
0	0	1	4
0	1	0	5
0	1	1	6
1	0	0	7
1	0	1	8
1	1	0	9
1	1	1	10

### 9.2.3 CFG3 register (isolated side)

The CFG3 register has the structure of [Table 35](#).

Table 35. CFG3 register

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	2LTOth				2LTOtime			
Default/reset	0000				0000			

The 2LTOth parameter sets the voltage value which is actively forced during the 2-level turn-off sequence (refer to [Section 7.10 on page 33](#) for details).



Table 36. 2LTOth

2LTOth [3 ... 0]				2LTO threshold value [V]
0	0	0	0	7.00
0	0	0	1	7.50
0	0	1	0	8.00
0	0	1	1	8.50
0	1	0	0	9.00
0	1	0	1	9.50
0	1	1	0	10.00
0	1	1	1	10.50
1	0	0	0	11.00
1	0	0	1	11.50
1	0	1	0	12.00
1	0	1	1	12.50
1	1	0	0	13.00
1	1	0	1	13.50
1	1	1	0	14.00
1	1	1	1	14.50

The 2LTOtime parameter sets the duration of the 2-level turn-off sequence (refer to [Section 7.10 on page 33](#) for details). If the 2LTOtime is set to zero, the 2-level turn-off feature is disabled.

**Table 37. 2-level turn-off time value**

2LTOtime [3 ... 0]				2-level turn-off time value [ $\mu$ s]
0	0	0	0	Disabled
0	0	0	1	0.75
0	0	1	0	1.00
0	0	1	1	1.50
0	1	0	0	2.00
0	1	0	1	2.50
0	1	1	0	3.00
0	1	1	1	3.50
1	0	0	0	3.75
1	0	0	1	4.00
1	0	1	0	4.25
1	0	1	1	4.50
1	1	0	0	4.75
1	1	0	1	5.00
1	1	1	0	5.25
1	1	1	1	5.50

### 9.2.4 CFG4 register (isolated side)

The CFG4 register has the structure of [Table 38](#).

**Table 38. CFG4 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	-	-	OVLO_EN	UVLOlatch	VLONth		VHONth	
Default/reset	-	-	0	0	00		00	

The OVLO\_EN bit enables the OVLO protection on the VH and VL power supply according to [Table 39](#).

**Table 39. VH and VL supply voltages OVLO enable**

OVLO_EN	OVLO supply voltage enable
0	Disabled
1	Enabled

The UVLOlatch bit sets if the UVLO is latched or not (refer to [Section 7.4 on page 29](#) for details).

**Table 40. UVLO protection management**

UVLOlatch	UVLO protection management
0	UVLO protection is not latched
1	UVLO protection is latched

The VLONth bits set the UVLO threshold on the negative power supply according to [Table 41](#).

Setting the parameter to zero disables the UVLO protection of the VL supply.

**Table 41. VL negative supply voltage UVLO threshold**

VLONth [1 ... 0]		Negative supply voltage UVLO threshold [V]
0	0	Disabled
0	1	-3
1	0	-5
1	1	-7

The VHONth bits set the UVLO threshold on the positive power supply according to [Table 42](#).

Setting the parameter to zero disables the UVLO protection of the VH supply.

**Table 42. VH positive supply voltage UVLO threshold**

VHONth [1 ... 0]		Positive supply voltage UVLO threshold [V]
0	0	Disabled
0	1	10
1	0	12
1	1	14

### 9.2.5 CFG5 register (isolated side)

The CFG5 register has the structure of [Table 43](#).

**Table 43. CFG5 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	-	-	-	-	2LTO_EN	CLAMP_EN	DESAT_EN	SENSE_EN
Default/reset	-	-	-	-	0	1	1	0

The 2LTO\_EN bit sets when the feature takes place according to [Table 44](#). Refer to [Section 7.10 on page 33](#) for details.

**Table 44. 2LTO mode**

2LTO_EN	2LTO mode
0	2LTO always active
1	2LTO active only after a fault event

The 2LTOth bit sets the 2-level turn-off threshold according to [Table 36 on page 57](#) and the 2-level turn-off time according to [Table 37](#).

The SENSE\_EN bit sets if the sense overcurrent function is enabled or not (refer to [Section 7.8 on page 33](#) for details).

**Table 45. SENSE comparator enabling**

SENSE_EN	SENSE comparator status
0	SENSE comparator disabled
1	SENSE comparator enabled

The DESAT\_EN bit sets if the desaturation protection is enabled or not (refer to [Section 7.6 on page 30](#) for details).

**Table 46. DESAT comparator enabling**

DESAT_EN	DESAT comparator status
0	DESAT comparator disabled
1	DESAT comparator enabled

Set the CLAMP\_EN bit to enable the Miller clamp feature (refer to [Section 7.9 on page 33](#) for details).

**Table 47. Miller clamp feature enabling**

CLAMP_EN	Miller clamp feature status
0	Miller clamp feature disabled
1	Miller clamp feature enabled

## 9.2.6 STATUS1 register (low voltage side)

The STATUS1 is a read only register that reports some device failure flags.

All flags are active high (the high value indicates a failure condition). The STATUS1 register has the structure of [Table 48](#).

**Table 48. STATUS1 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	OVLOH	OVLOL	DESAT	SENSE	UVLOH	UVLOL	TSD	TWN
Default <sup>(1)</sup>	0	0	0	0	1	0	0	0
Reset	0	0	0	0	0	0	0	0

1. Default value of the local copy of the register. The value will be updated according to the actual information from the isolated side. The default is forced at the device power-up, when the registers are reset all the flags are forced low (no failures).

A description of the STATUS1 register bits is provided in [Table 49](#).

**Table 49. STATUS1 register description**

Name	Bit	Fault	Latched	Force "safe state"	Note
OVLOH	7	VH overvoltage flag. It is forced high when VH is over $OV_{VHoff}$ threshold.	Always	Yes	-
OVLOL	6	VL overvoltage flag. It is forced high when VL is over $OV_{VLoft}$ threshold.	Always	Yes	-
DESAT	5	Desaturation flag. It is forced high when DESAT pin voltage reach $V_{DESATth}$ threshold.	Always	Yes	-
SENSE	4	Sense flag. It is forced high when SENSE pin voltage reach $V_{SENSEth}$ threshold.	Always	Yes	-
UVLOH	3	VH undervoltage flag. It is forced high when VH is below $VH_{off}$ threshold.	When UVLOlatch is high only	Yes	If not latched (UVLOlatch low) UVLOH returns low when VH is over $VH_{on}$ threshold.
UVLOL	2	VL undervoltage flag. It is forced high when VL is over $VLoft$ threshold.	When UVLOlatch is high only	Yes	If not latched (UVLOlatch low) UVLOL returns low when VL is below $VLoft$ threshold.
TSD	1	Thermal shutdown protection flag. It is forced high when overtemperature shutdown threshold is reached.	No (hysteresis)	Yes	-
TWN	0	Thermal warning flag. It is forced high when overtemperature shutdown threshold is reached.	No (hysteresis)	No	-

### 9.2.7 STATUS2 register (low voltage side)

The STATUS2 is a read only register. The STATUS2 register has the structure of [Table 50](#).

**Table 50. STATUS2 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	-	-	-	-	-	REGERRR	ASC	-
Default <sup>(1)</sup>	x	x	x	x	x	1	0	x
Reset	x	x	x	x	x	0	0	x

1. Default value of the local copy of the register. The value will be updated according to the actual information from the isolated side. The default is forced at the device power-up, when the registers are reset all the flags are forced low (no failures).

A description of the STATUS2 register bits is provided in [Table 51](#).

**Table 51. STATUS2 register description**

Name	Bit	Fault	Latched	Force "safe state"	Note
REGERRR	2	Register or communication error on isolated side. It is forced high when: – Programming procedure is not correctly performed. – Isolated interface communication fails. – An unexpected register value change occurs in one of the remote registers. It is also latched at power-up/reset and from Sleep state.	Always	Yes	-
ASC	1	ASC pin status. When ASC pin is high the flag reports '1', otherwise is '0'.	No	No	See details in <a href="#">Section 7.12 on page 36</a>

### 9.2.8 STATUS3 register (low voltage side)

The STATUS3 is a read only register. The STATUS3 register has the structure of [Table 52](#).

**Table 52. STATUS3 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	-	-	-	DT_ERR	SPI_ERR	REGERRL	OVLOD	UVLOD
Default <sup>(1)</sup>	x	x	x	0	0	1	0	1
Reset	x	x	x	0	0	0	0	0

1. The default is forced at the device power-up, when the registers are reset all the flags are forced low (no failures).

A description of the STATUS3 register bits is provided in [Table 53](#).

**Table 53. STATUS3 register description**

Name	Bit	Fault	Latched	Force "safe state"	Note
DT_ERR	4	Deadtime error flag. This bit is forced high when a violation of internal DT is detected.	Always	No	See details in <a href="#">Section 7.2 on page 26</a>
SPI_ERR	3	SPI communication error flag. It is forced high when the SPI communication fails cause: – Wrong CRC check. – Wrong number of CK rising edges. – Attempt to execute a not-allowed command. Attempt to read, write or reset at a not-available address.	Always	No	-
REGERRL	2	Register or communication error on low voltage side. It is forced high when: - – Programming procedure is not correctly performed. – Isolated interface communication fails. – An unexpected register value change occurs in one of the remote registers. It is latched at power-up/reset also.	Always	Yes	-
OVLOD	1	VDD overvoltage flag. It is forced high when VDD is over OVVDOff threshold.	Always	Yes	-
UVLOD	0	VDD undervoltage flag. It is forced high when VDD is below VDDon threshold. It is latched at power-up/reset also.	Always	Yes	-

### 9.2.9 TEST1 register (isolated side)

The TEST1 register has the structure of [Table 54](#).

**Table 54. TEST1 register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	-	-	-	GOFFCHK	GONCHK	DESCHK	SNSCHK	RCHK
Default/reset	x	x	x	0	0	0	0	0

Setting an one check bit of the register enables the respective check mode.

**Table 55. Check mode**

Bit	Check mode
RCHK	SENSE resistor
SNSCHK	SENSE comparator
DESCHK	DESAT comparator
GONCHK	GON to gate path
GOFFCHK	GOFF to gate path

**9.2.10 DIAG1CFG and DIAG2CFG registers (low voltage side)**

The DIAG1CFG register has the structure of [Table 56](#).

**Table 56. DIAG1CFG register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	DIAG1_7	DIAG1_6	DIAG1_5	DIAG1_4	DIAG1_3	DIAG1_2	DIAG1_1	DIAG1_0
Default/reset	1	1	0	1	1	0	1	0

The DIAG2CFG register has the structure of [Table 57](#).

**Table 57. DIAG2CFG register**

-	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
-	DIAG2_7	DIAG2_6	DIAG2_5	DIAG2_4	DIAG2_3	DIAG2_2	DIAG2_1	DIAG2_0
Default/reset	0	0	0	0	0	0	0	0

If a bit in the DIAG1CFG register is high, the corresponding fault events turn on the open drain connected to the DIAG1 pin forcing the output low.

If a bit in the DIAG2CFG register is high and the DIAG\_EN bit is high, the corresponding fault events turn on the open drain connected to the DIAG2 pin forcing the output low.



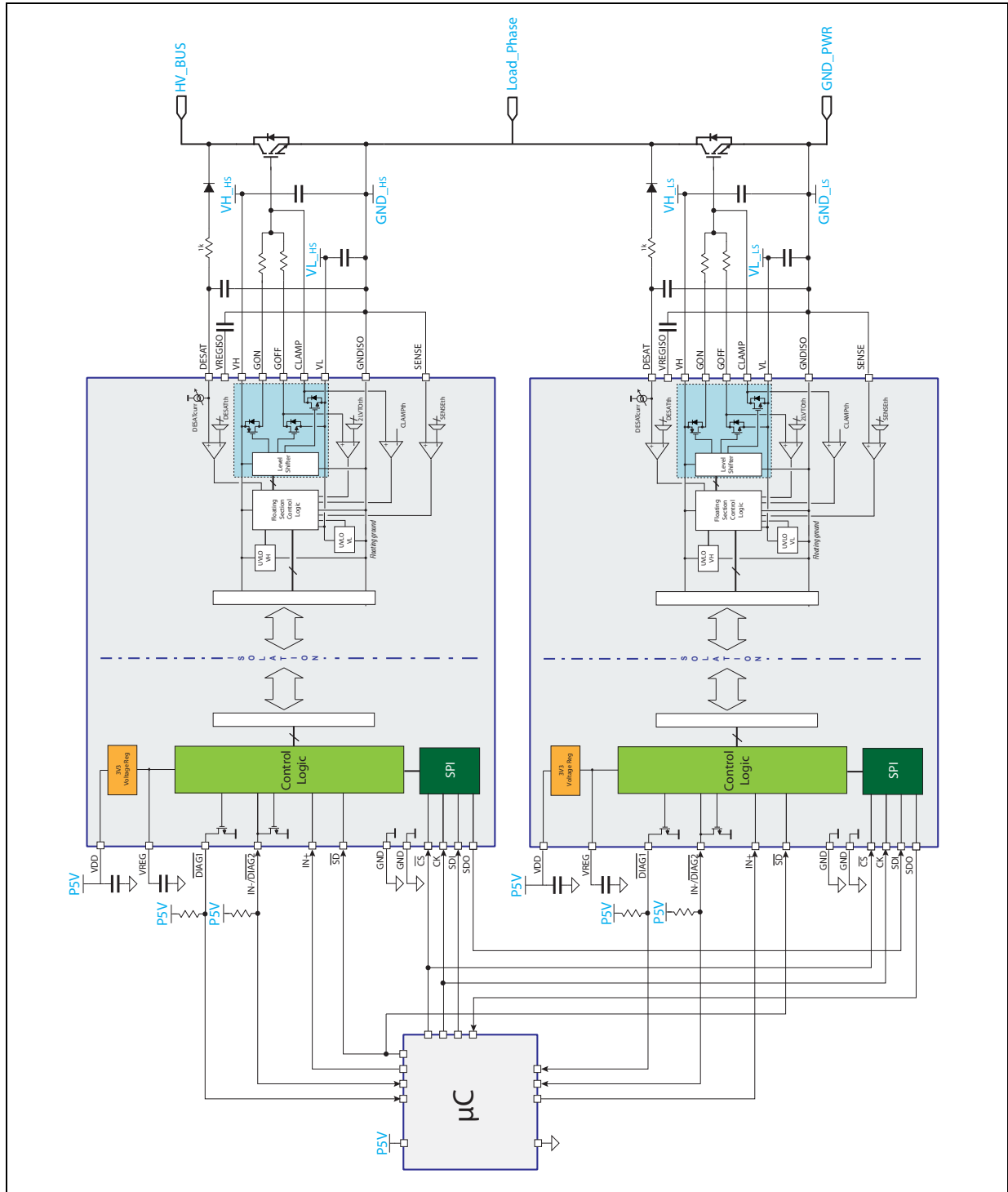
The relation between the DIAG1CFG and DIAG2CFG register bits and failure events is described in [Table 58](#).

**Table 58. Relation between DIAGxCFG bits and failure conditions**

DIAGxCFG bit	Failure	Status registers bit
0	Thermal warning	TWN
1	Thermal shutdown	TSD
2	ASC feedback	ASC, DT_ERR
3	Desaturation and sense detection	DESAT, SENSE
4	Overvoltage failure	OVLOH, OVLLOL
5	Undervoltage failure	UVLOH, UVLLOL
6	VDD power supply failure	UVLOD, OVLOD
7	SPI communication error or register failure	SPI_ERR, REGERRL, REGERRR

# 10 Typical application diagram

Figure 25. Typical application diagram in half-bridge configuration



Refer to [Figure 12 on page 32](#) in the dedicated [Section 7.7 on page 31](#) for the connection of the VCECLAMP pin.

# 11 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

## 11.1 SO24W package information

Figure 26. SO24W package outline

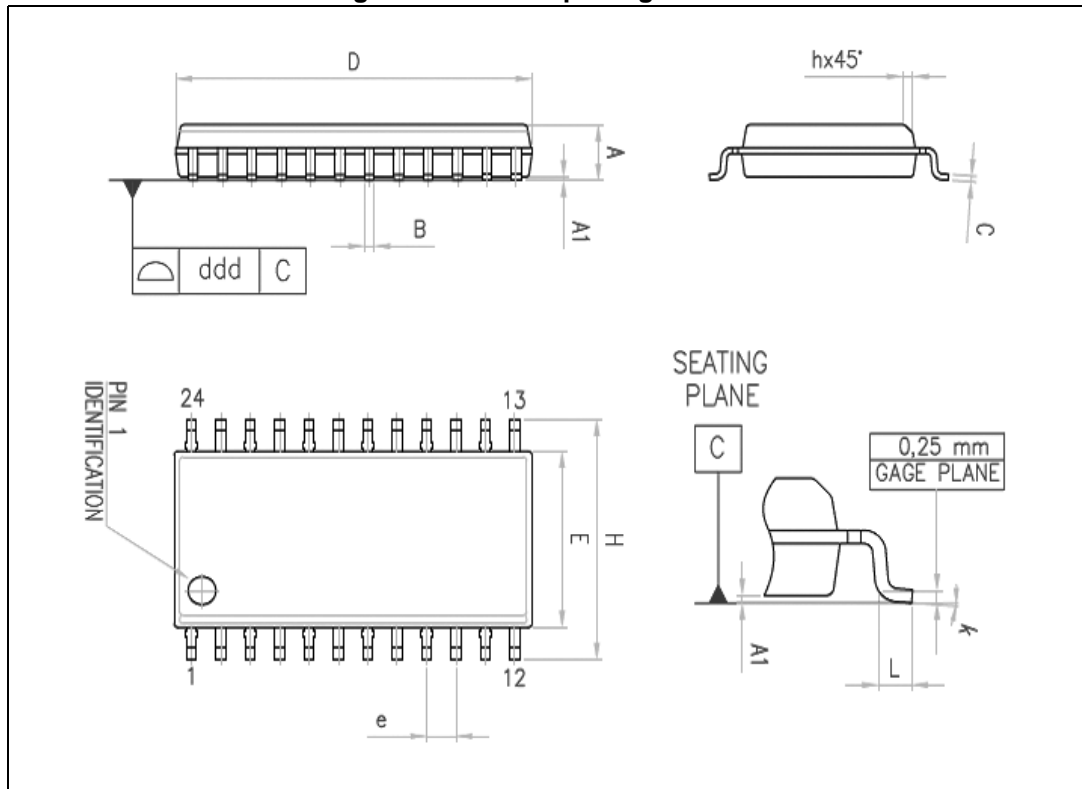
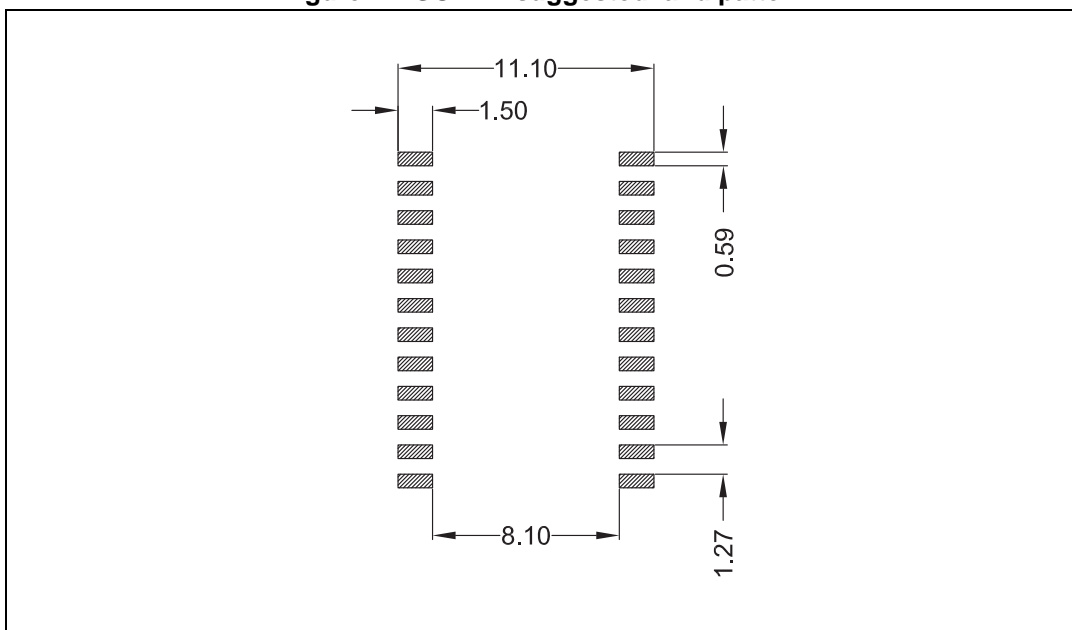


Table 59. SO24W package mechanical data

Symbol	Dimensions (mm)			Notes
	Min.	Typ.	Max.	
A	2.35	-	2.65	-
A1	0.10	-	0.30	-
B	0.33	-	0.51	-
C	0.23	-	0.32	-
D	15.20	-	15.60	(1)
E	7.40	-	7.60	-
e	-	1.27	-	-
H	10.00	-	10.65	-
h	0.25	-	0.75	-
L	0.40	-	1.27	-
K	0	-	8	Degrees
ddd	-	-	0.10	-

1. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per side.

Figure 27. SO24W suggested land pattern



## 12 Ordering information

**Table 60. Device summary**

Order code	Package	Packing
STGAP1AS <sup>(1)</sup>	SO24W	Tube
STGAP1ASTR <sup>(1)</sup>	SO24W	Tape and reel

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

## 13 Revision history

**Table 61. Document revision history**

Date	Revision	Changes
10-Jun-2016	1	Initial release.
02-Sep-2016	2	Updated main title <i>on page 1</i> . Updated <i>Figure 1 on page 8</i> (replaced by new figure). Updated "VREG" values in <i>Table 4 on page 12</i> . Minor modifications throughout document.

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